



**Nissan Chemical**  
CORPORATION

# Presentation for R&D of Performance Materials

June 21, 2022

Nissan Chemical Corporation  
Performance Materials Division  
Materials Research Laboratories

Translation of presentation materials for the R&D of  
Performance Materials held on June 21,2022

# 1. Business Strategy of Performance Materials Segment

## Contents

FY2021 Financial Results by Segment

Main Products and Development Products

Semiconductor Field

Display Field

New Mid-term Business Plan

(¥billion)

		FY2021 (Actual)	FY2021 (Plan)	FY2021 (Actual vs. Plan)
		①	②	①-②
Chemicals	Sales	37.6	43.1	-5.5
	OP	3.8	5.1	-1.3
Performance Materials	Sales	81.7	75.1	+6.6
	OP	27.7	17.3	+10.4
Agro- chemicals	Sales	65.8	70.1	-4.3
	OP	18.3	21.1	-2.8
Pharma- ceuticals	Sales	6.6	7.5	-0.9
	OP	0.9	0.7	+0.2
Others	Sales	16.3	39.2	-22.9
	OP	0.3	-1.2	+1.5
Total	Sales	208.0	235.0	-27.0
	OP	51.0	43.0	+8.0

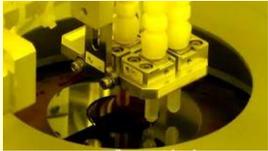
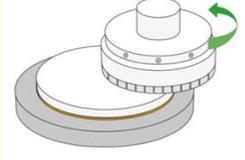
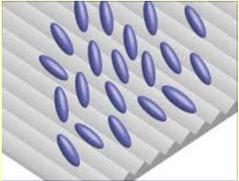
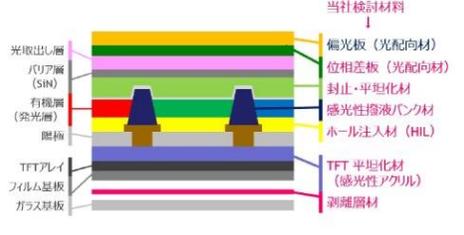
## Major Difference Factors in Operating Profit

Melamine	- Lower domestic demand, export decrease, etc.
Environmental Related Products	- Sales decrease of HI-LITE, etc.
Photo IPS	- Sales increase due to widening target applications, etc.
ARC®*1	- Sales increase due to increased demand and expansion of market share, etc.
Acquired Agrochemical Products	- Sales increase due to expansion of QUINTEC(QUINOXYFEN) and DITHANE(MANCOZEB)
Fluralaner	- Sales decrease due to inventory adjustments
LIVALO	- Sales increase in domestic market
Custom Chemicals	- Sales decrease of GE API*2 - Delayed plan of peptide CMO
Adjustments etc.	- Effects of changes in accounting policies (-¥22.9 billion is included in sales of "Others")

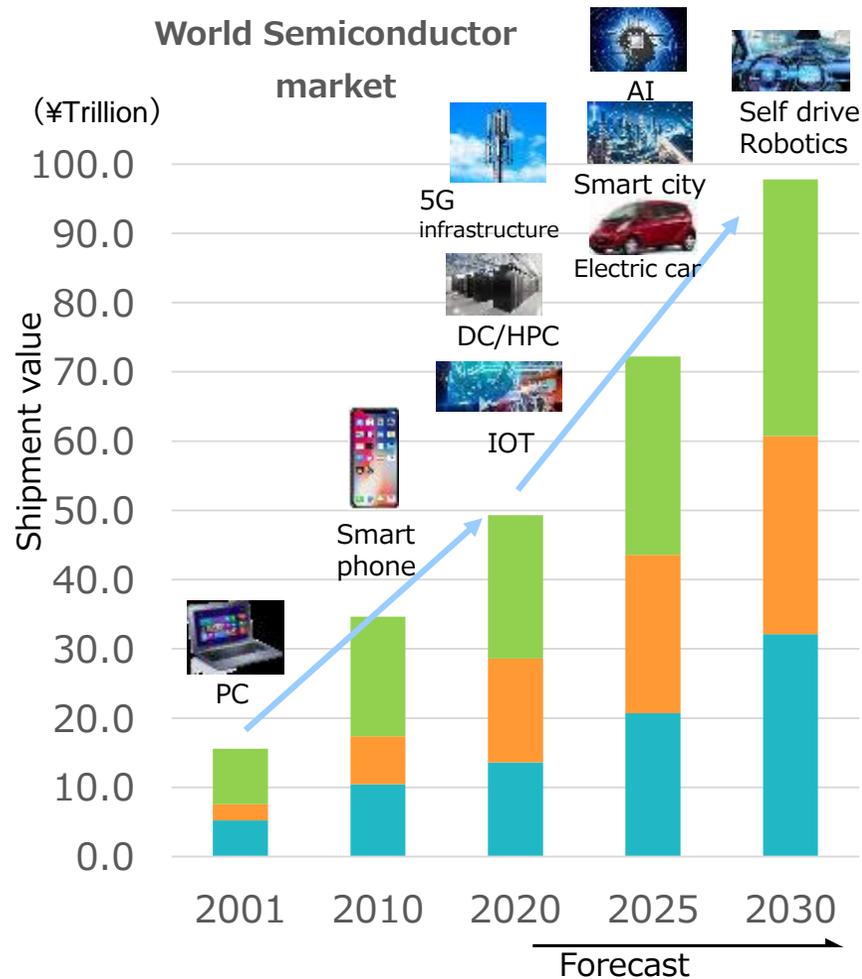
\*1: ARC® is a registered trademark of Brewer Science, Inc.

# Main Products and Development Products

Continue to expand the business by actively developing display related materials and semiconductor related materials.

	Main Products	Development products	R&D
Semiconductor	BARC Multi-layer materials  Polishing materials  Temporary bonding materials	EUV-UL Image sensors materials DSA materials RDL materials	Semiconductor materials research dept. Inorganic materials research dept.
	LC alignment materials Photo alignment materials  Hard coating materials	OLED related materials  LCD related materials Micro LED related materials	Advanced materials research dept. Display materials research dept.

# Semiconductor Field Semiconductor Market



	Market size (2018) ¥trillion	Product example	Main company
Logic	21	Processor	intel tsmc
		GPU	QUALCOMM NVIDIA
		SoC	
Memory	18	DRAM	SAMSUNG SK hynix
		NAND	Micron KIOXIA
Others	15	Analogue IC	Infineon SONY
		Power IC	ON Semiconductor MITSUBISHI ELECTRIC
		Image sensor	

(Source) Ministry of Economy, Trade and Industry, Materials of November 2021 the 4th Semiconductor and Digital Industry Strategy Review Conference

# Semiconductor Field

## Execution of Capital Investment

Strengthen the production system for semiconductor materials and expand advanced evaluation functions.

### 1) New plant construction

NCK Co., Ltd. 3<sup>rd</sup> plant

Place	Daxin-si Songsan 2 Industrial Complex, Chungcheongnam-do, Korea
Business	Manufacturing of semiconductor materials
Starting plan of sales operation	2024/2Q
Leasehold area	40,423m <sup>2</sup>
Investment amount	8.5 Billion JPY



### 2) Capital investment

Installation of Advanced defect detection tool SP-7

Installed in 2021

Strengthening of evaluation tools

Planning in Toyama and NCK



# Semiconductor Field Lithography Materials



Logic, DRAM  
Critical layers

EUV underlayer

High NA EUV

DSA materials

Logic, DRAM  
Non-critical layer,  
3D-NAND

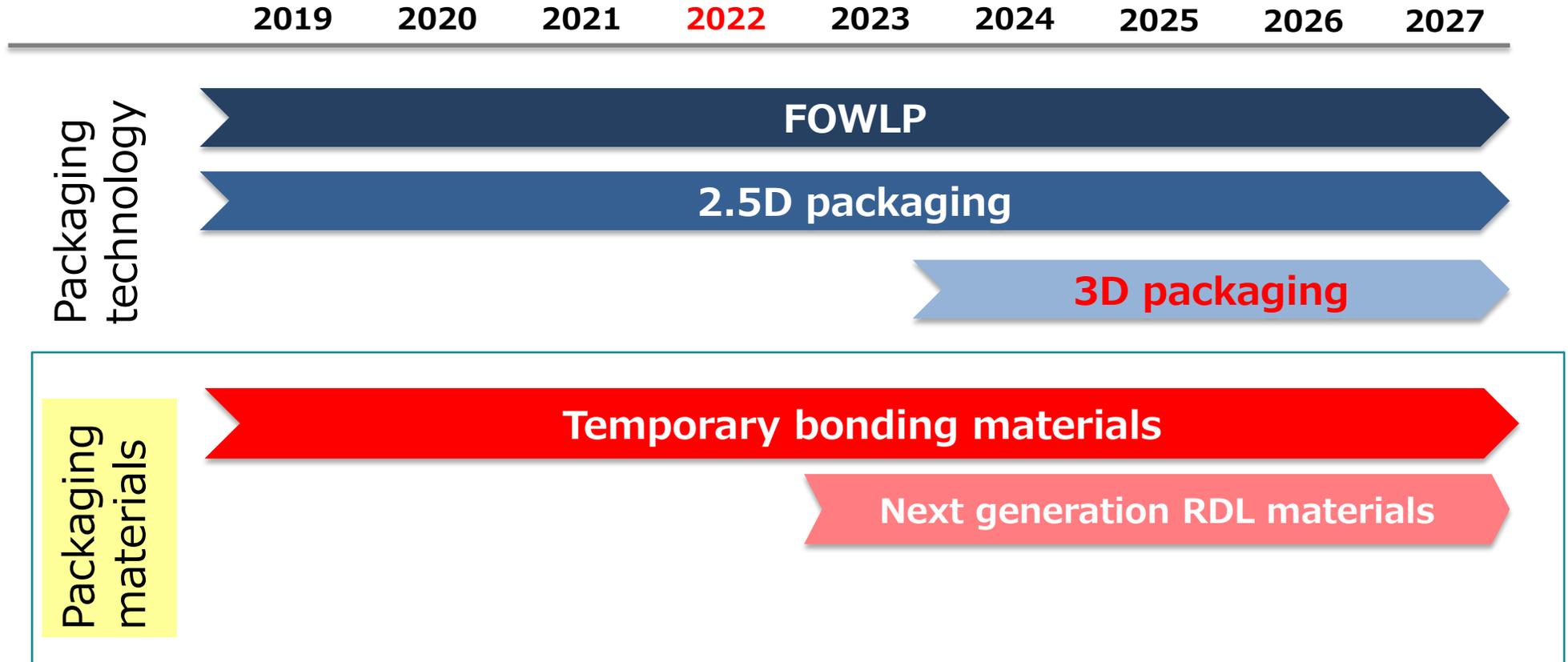
ArF/ArF immersion BARC

ArF/ArF immersion multilayer materials

Surely acquire next generation demands

# Semiconductor Field

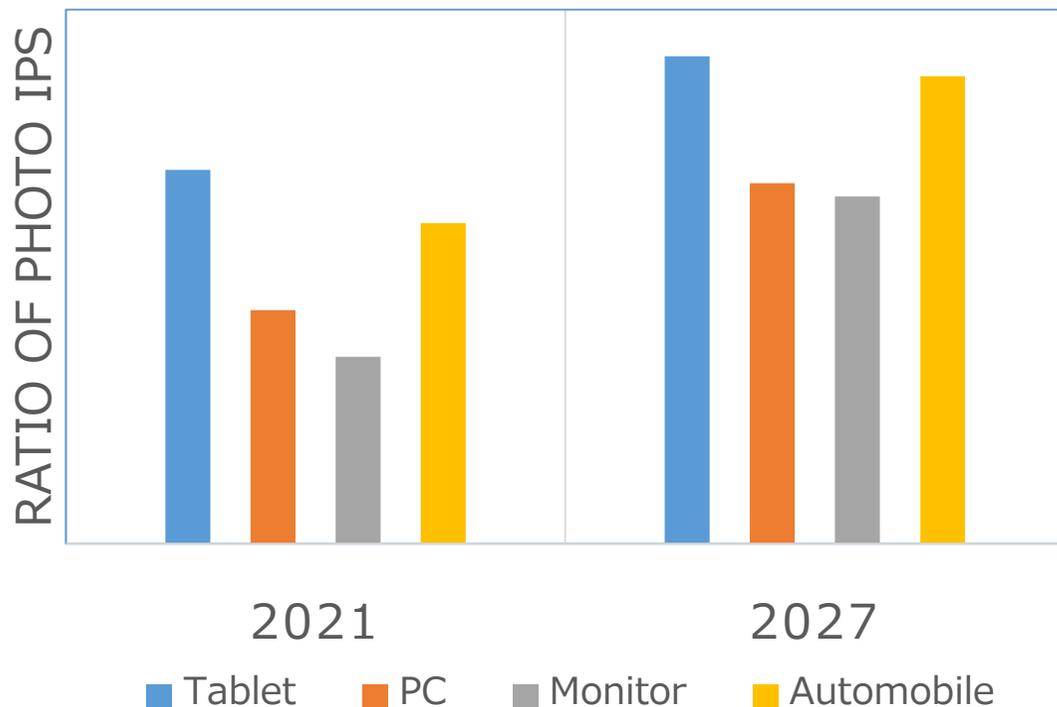
## 3D Packaging Related Materials



Strengthen development of materials for next generation packaging

# Display Field Expansion of Application for Photo IPS

Ratio of photo IPS in each display application  
(Our estimate)



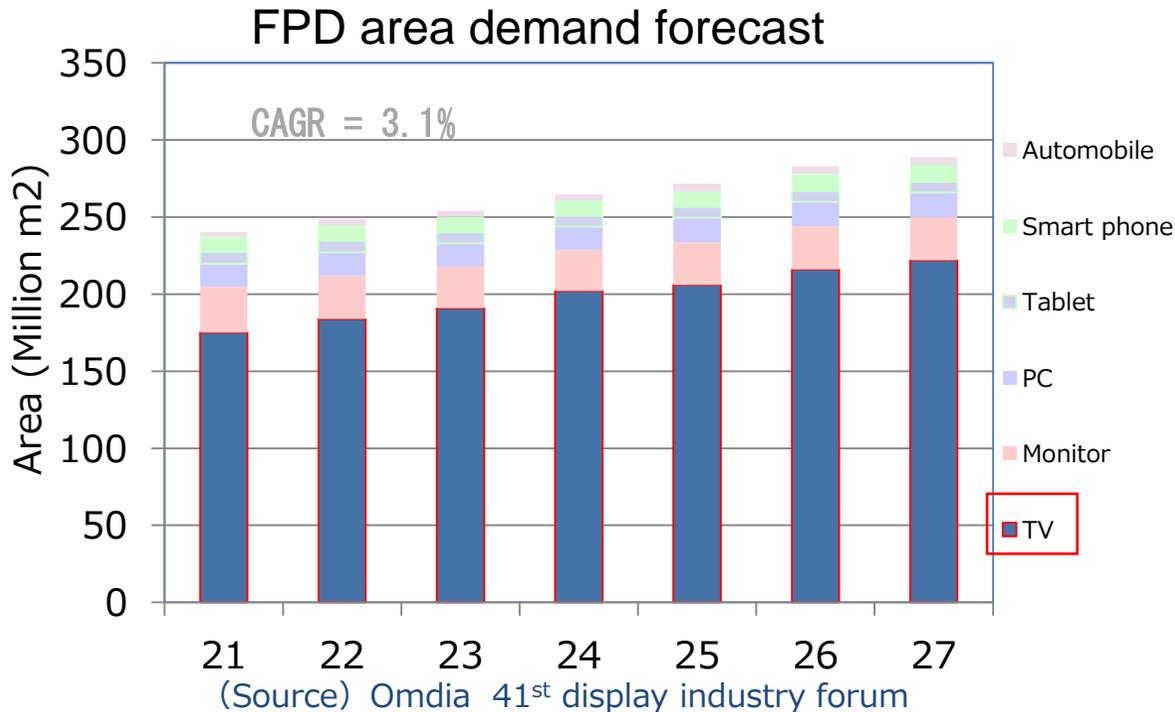
The transition from IPS (rubbing) to photo IPS is progressing, and it is expected that the applications of photo IPS will expand.



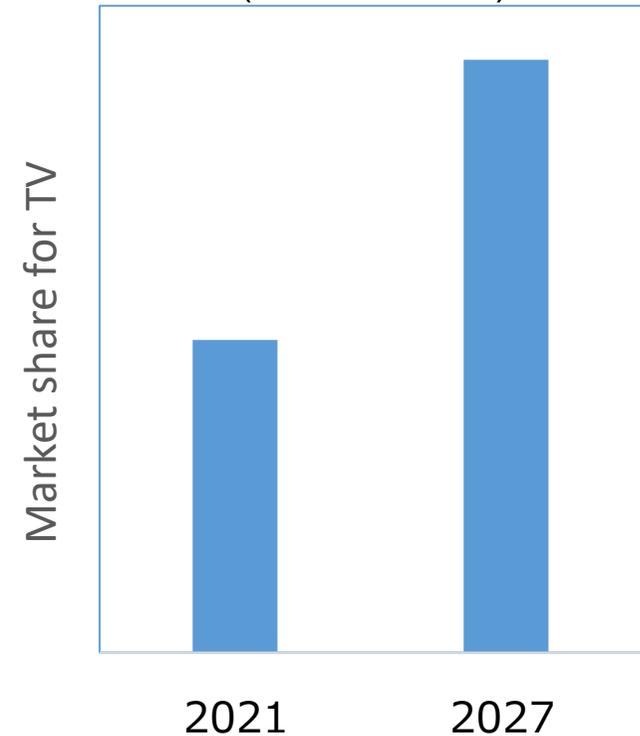
By continuously improving the characteristics, we will maintain a high market share of photo IPS and achieve the sales expansion!

# Display Field

## Expansion of market share of Alignment Materials for TV



### Target of NCC's market share for TV (Our estimate)

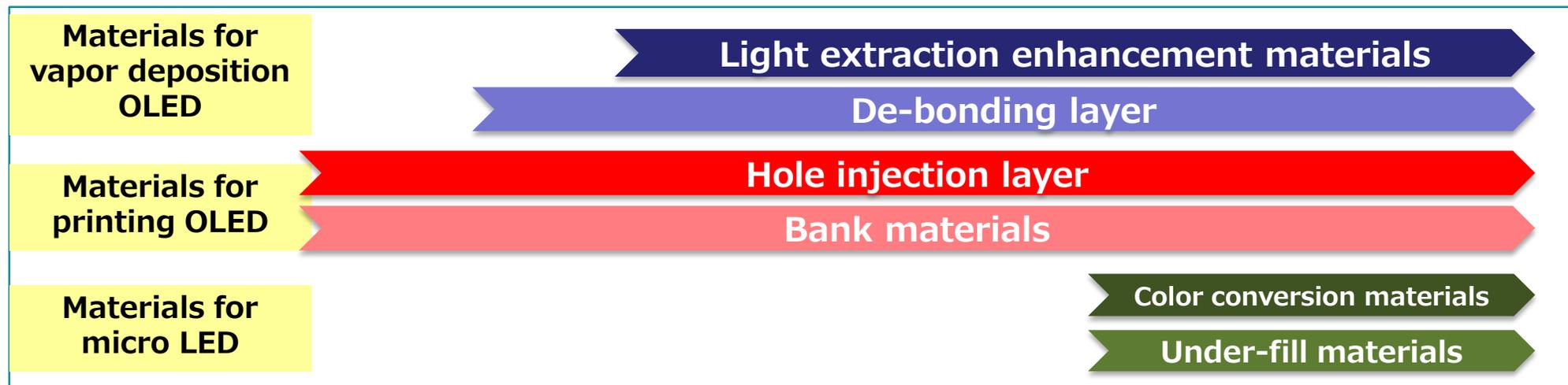
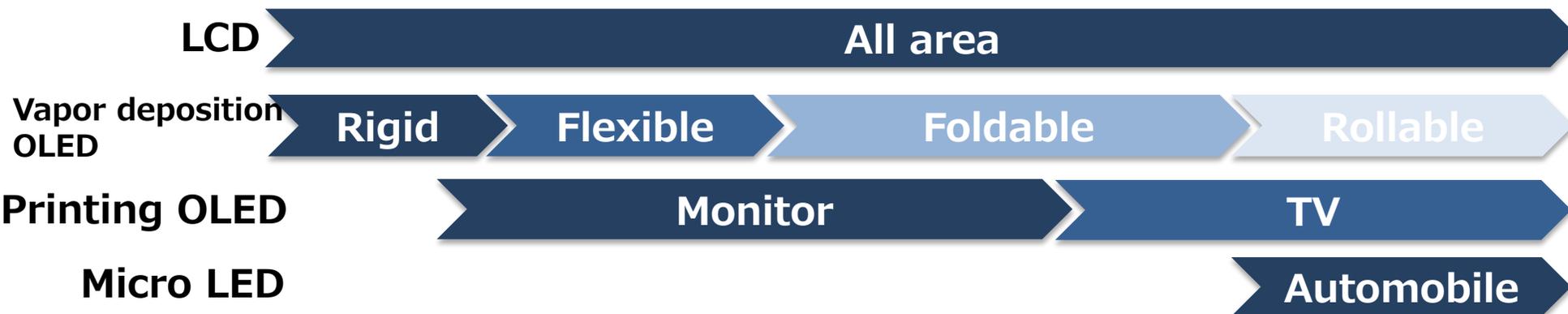


TV applications are expected to continue expanding.

Target to further sales expansion by achieving higher market share of alignment materials for TV.

# Display Field New Material Development

2019 2020 2021 2022 2023 2024 2025 2026 2027



Proposing materials for next-generation display that are environmentally friendly

# New Mid-term Business Plan

## Opportunities and Risks

- OLED market expansion and LCD market contraction
- Slowdown of semiconductor miniaturization and progress in 3D packaging technology
- Development of a smart society
- Intensified competition among companies

## Main Measures

- Improve existing products and expand their applications
- Reinforce and increase manufacturing facilities and other facilities
- Develop and launch new products onto the market
- Start the commercial operation of the new NCK plant
- Improve profitability of the inorganic material (inorganic colloid) business

## Sources of Growth

- Photo IPS
- Photo VA
- OLED materials
- Semis materials(ARC<sup>®</sup>\*1, EUV materials, multi layer materials/ 3D packaging process materials)
- SNOWTEX

## Major Investment Plans

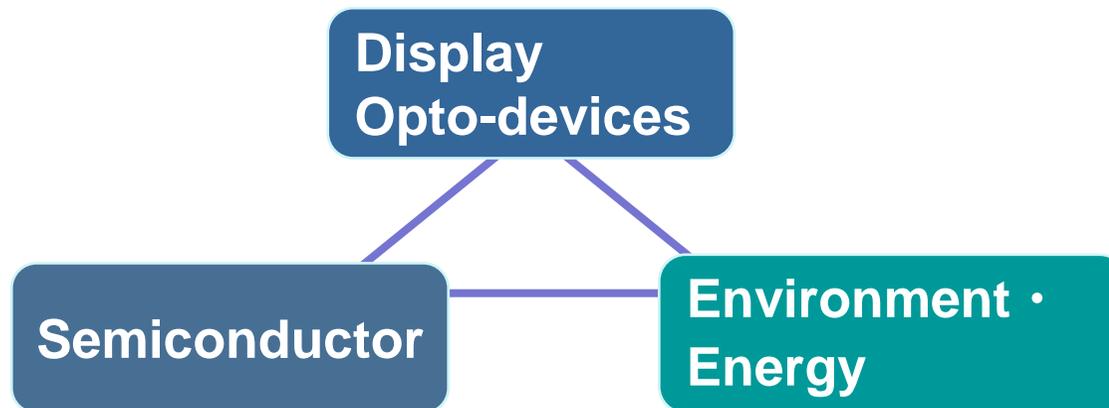
- Engineering work to strengthen DP3 facility ¥0.5 billion
- Installing semiconductor evaluation equipment ¥1.2 billion
- Establishing a new NCK plant for semis materials ¥8.5 billion

	FY2021 (Actual)	FY2022 (Outlook)	FY2024 (Plan)	FY2027 (Plan)	(¥billion)	
					FY2024 vs. FY2021	FY2027 vs. FY2021
Sales	81.7	89.9	102.9	117.2	+21.2	+35.5
OP	27.7	30.5	32.1	38.0	+4.4	+10.3
Capex	5.7	8.3	13.2	-	+7.5	-
Depreciation	3.9	4.7	8.7	-	+4.8	-
R&D expenses	7.0	7.8	8.9	-	+1.9	-

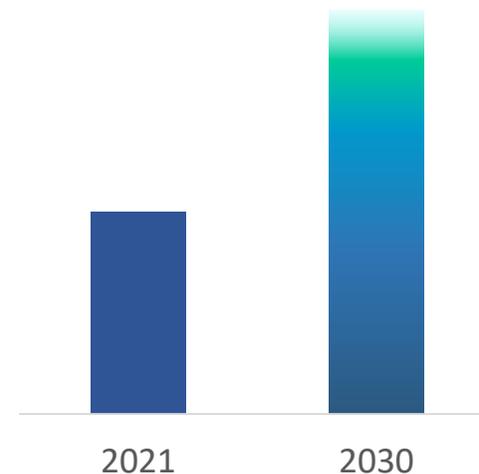
\*1: ARC<sup>®</sup> is a registered trademark of Brewer Science, Inc.

# How to realize our portfolio we aim for

Establish a more balanced material portfolio that can contribute to the environment as well as to the convenience of society



- Expand applications for existing products
- Promote new product development and expand the sales
- Establish new business field



## 2. R & D Overview for Future Growth

### Contents

Introduction of Materials Research Laboratories

Semiconductor Materials Research Department

Display Materials Research Department

Advanced Materials Research Department

Inorganic Materials Research Department

# Introduction of Materials Research Laboratories

## Chiba



**Chemical Research  
Laboratories  
Funabashi**

## Chiba



**Materials Research  
Laboratories  
Funabashi**



**Materials Research  
Laboratories  
Sodegaura**

## Toyama



**Materials Research  
Laboratories  
Toyama**

## Saitama



**Biological Research  
Laboratories  
Shiraoka**

## China (Suzhou)



**Nissan Chemical  
Materials Research  
(Suzhou) Co., Ltd.**

## Korea (Pyeongtaek)



**NCK Co., Ltd**

## Taiwan (Kaohsiung)



**Nissan Chemical  
Taiwan Co., Ltd**

# Semiconductor Materials

# C o n t e n t s

Introduction

Lithography Materials  
(EUV Materials)

Packaging Materials  
(Temporary bonding materials)

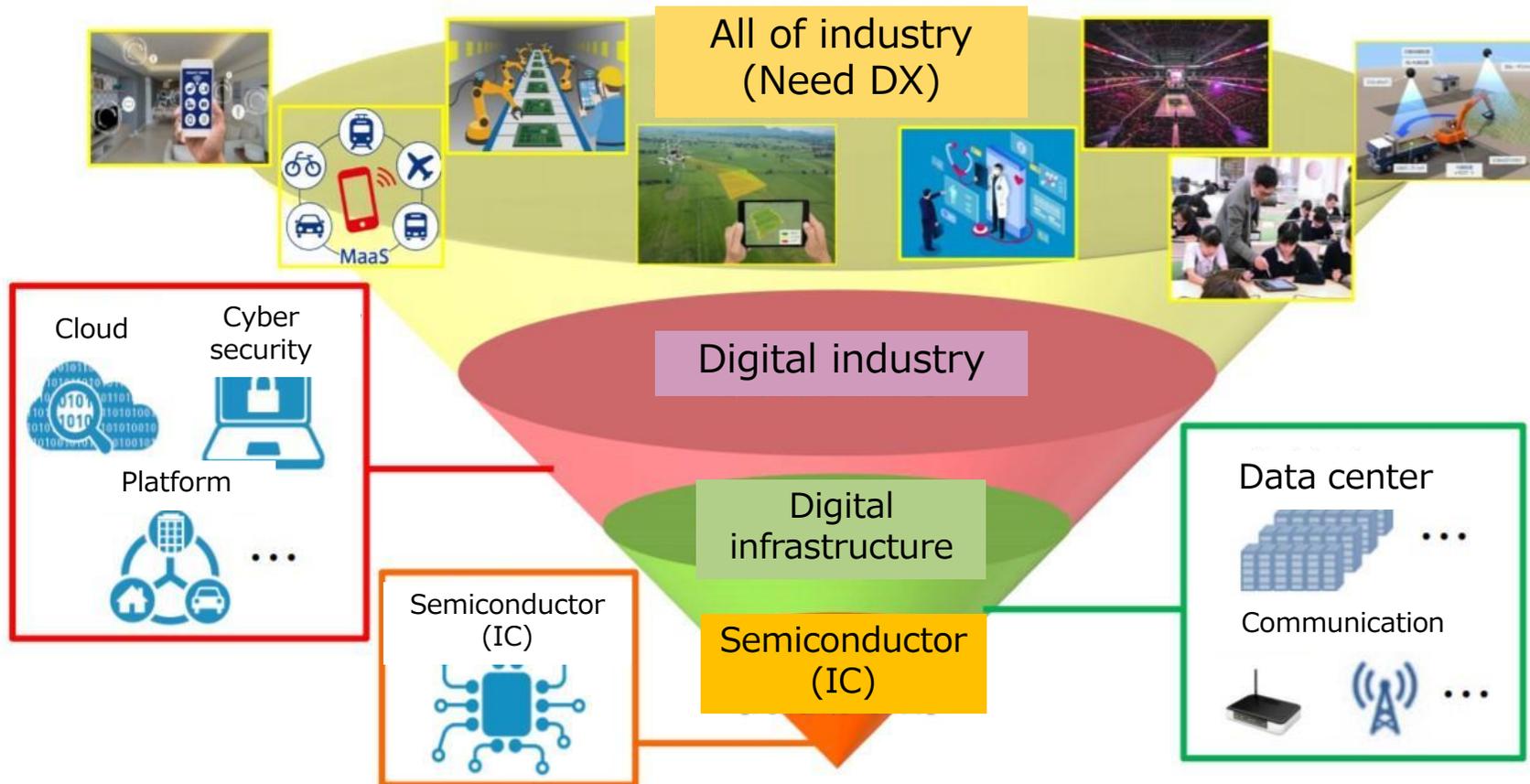
# C o n t e n t s

## Introduction

Lithography Materials  
(EUV Materials)

Packaging Materials  
(Temporary bonding materials)

**DX have been expanded rapidly because of Covid-19.**  
**“Miniaturization and 3D packaging technology” will be strongly required.**



Source: Ministry of Economy, Trade and Industry  
Semiconductor / Digital Industry Strategy 2021.6

# Miniaturization Road Map

2019    2020    2021    **2022**    2023    2024    2025    2026    2027



193nm Imm.

EUV (13.5nm) **Used as Leading Edge Tech.**

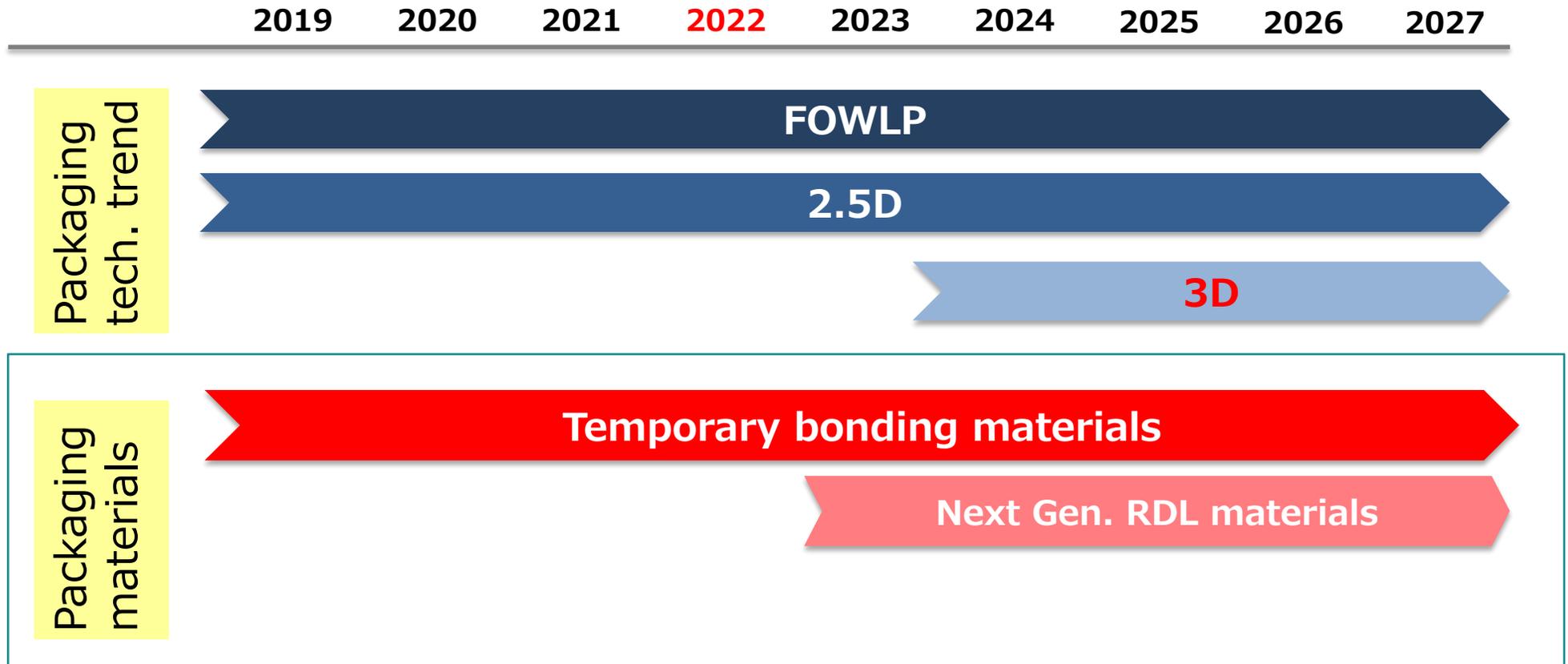
Started R&D

**High-NA EUV**

DSA(Direct Self Assembly)

- Miniaturization will continue up to 1nm node. (Mass production ~2025)
- EUV lead the miniaturization further.

Miniaturization Technology



**Chip performance could be dramatically improved by combination of miniaturization and 3D integration.  
Chiplet tech. can move forward the 3DIC market expand.**

## FEOL Lithography Materials

### Resist Under layers

BARC (i line, ArF, KrF)  
Gap fill materials  
EUV-UL  
SiHM  
SOC  
DSA-NL

## BEOL Packaging Materials

### Materials for Wafer Thinning process

Temporary Bonding Materials

**New Project**  
(Litho. & Package)

### 【R&D Strategy】

- Focus to Resist Under layer materials based on Lithography road map (FEOL)
- Develop materials for wafer thinning process (BEOL)
- Finding new project based on our own technology in Litho. and packaging area

# C o n t e n t s

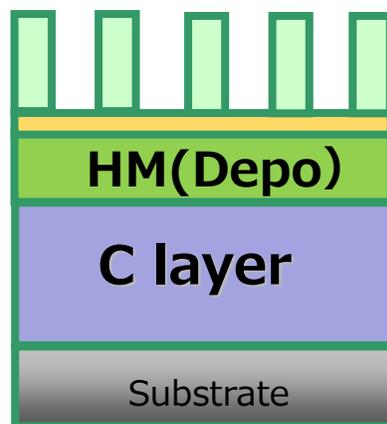
Introduction

**Lithography Materials**  
(EUV Materials)

Packaging Materials  
(Temporary bonding materials)

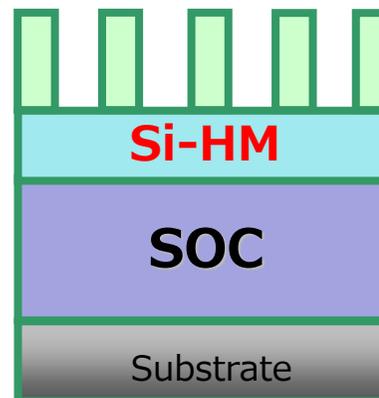
## Lithography Materials (EUV-UL, EUV-SiHM)

### 4 layer process



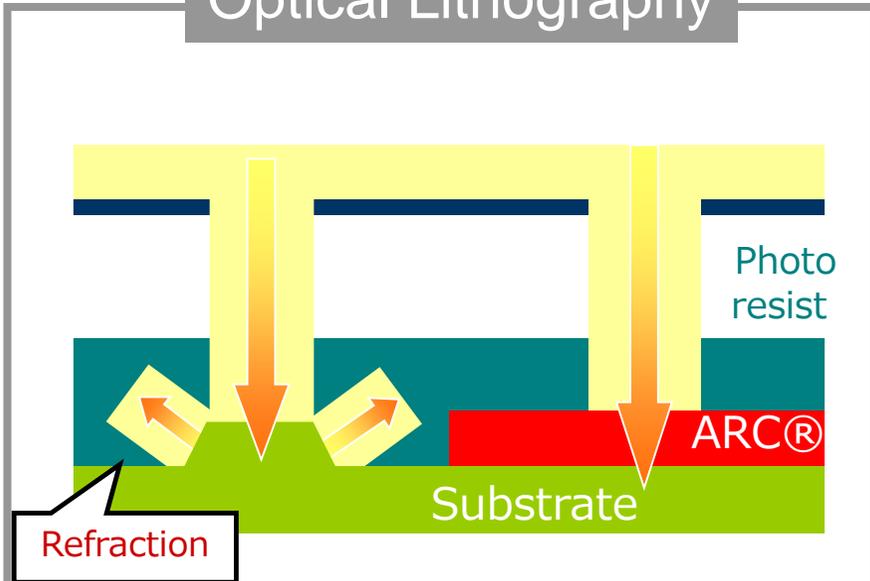
**EUV-UL**

### Tri layer process



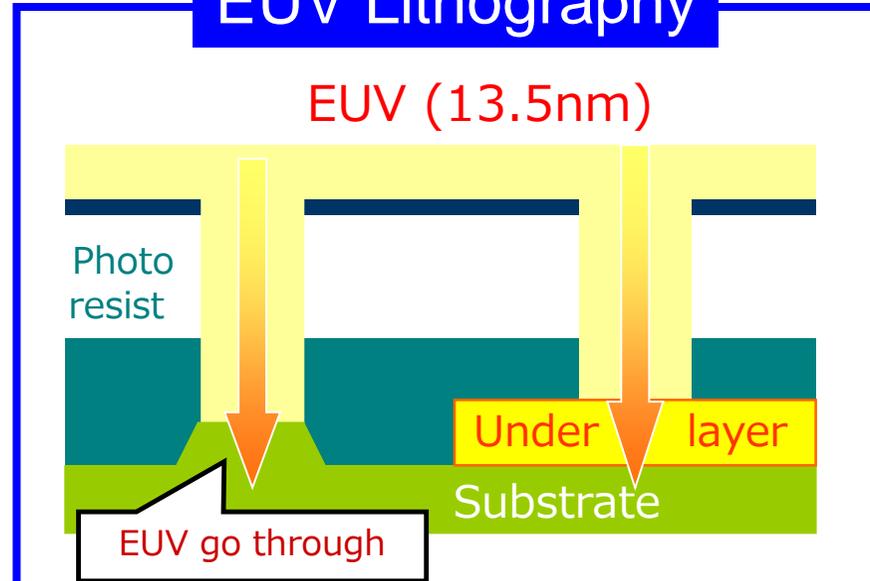
## Optical and EUV Lithography

### Optical Lithography



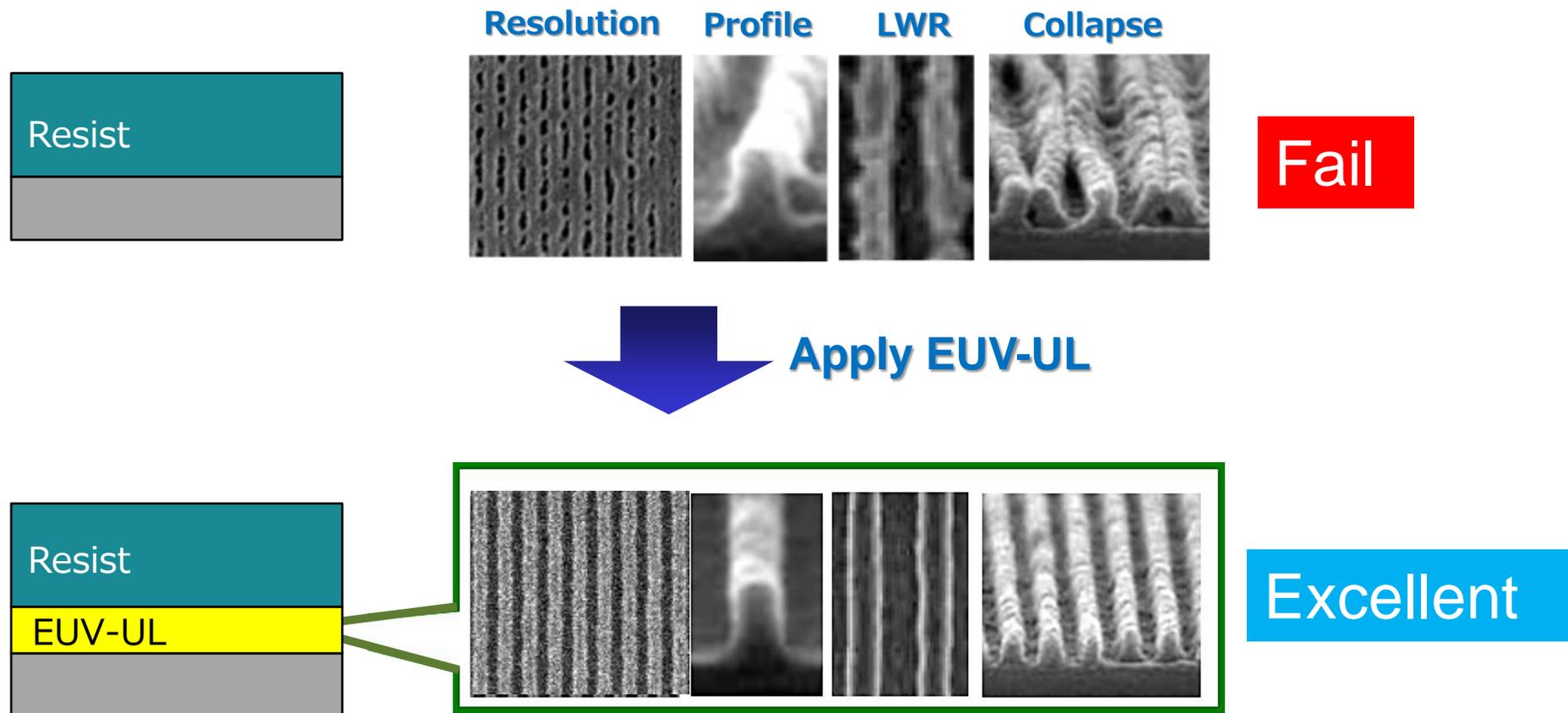
Anti-Reflective Coating (ARC®) is necessary to control the light reflection from substrate.

### EUV Lithography

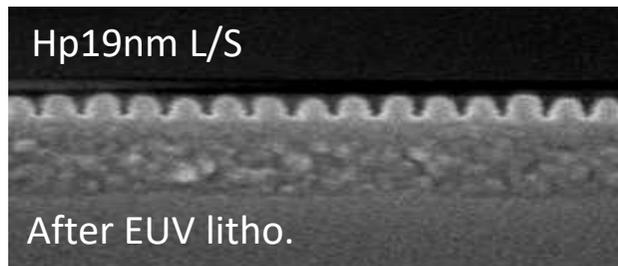
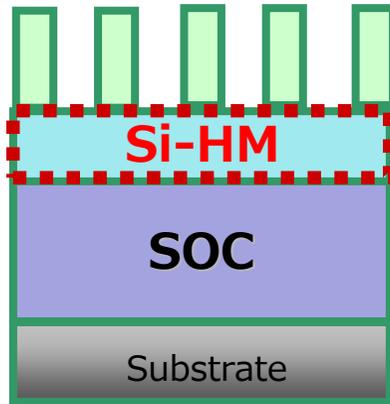


Anti-Reflective Coating (ARC®) is NOT necessary for EUV. Because of no reflection from sub.

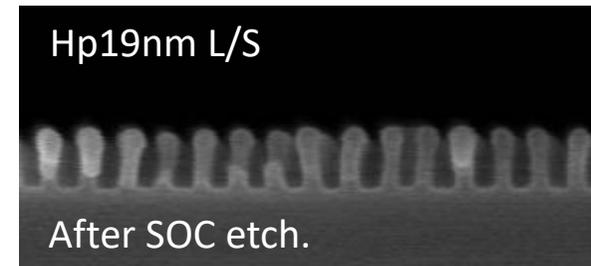
\*ARC® is registered trade mark of Brewer Science, Inc.



**EUV-UL MUST BE** necessary for EUV lithography  
⇒ Applied for HVM

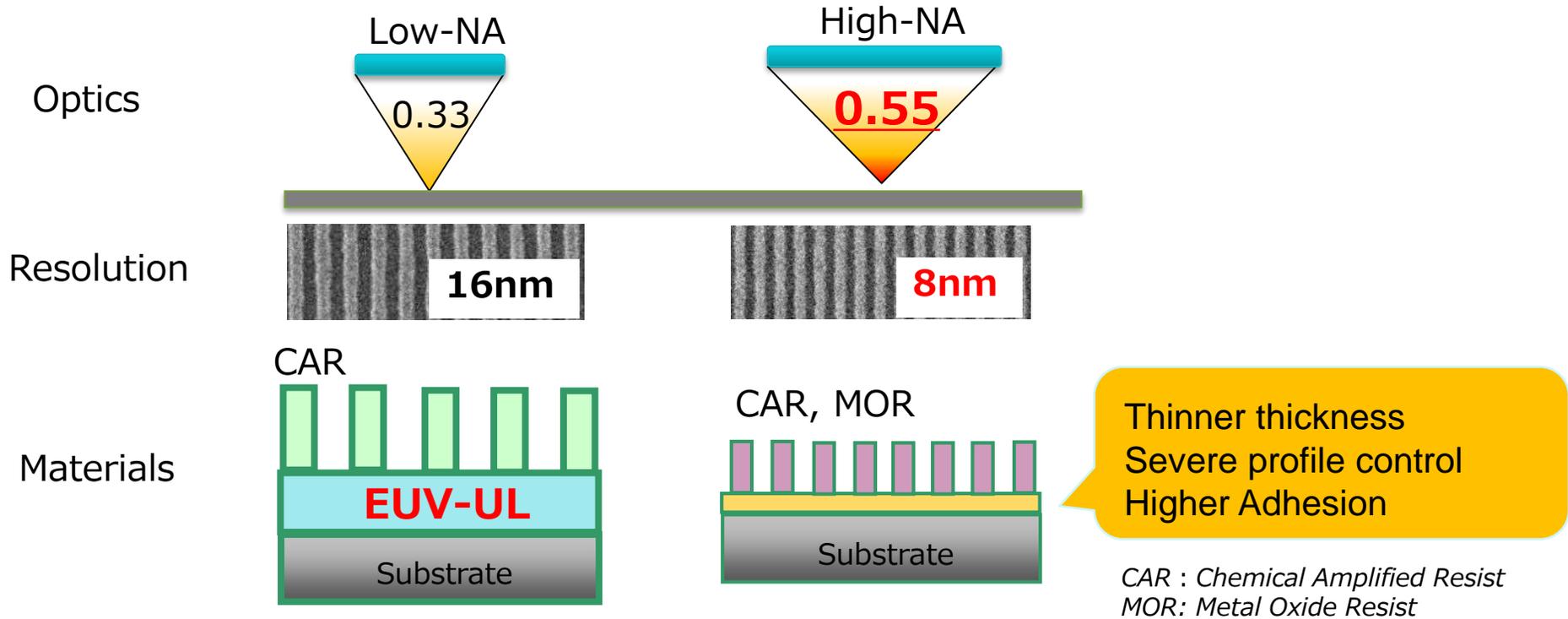


Good resist profile



Good etch performance

**EUV-SiHM in TRL stack **MUST BE** necessary for EUV.  
⇒ Applied for HVM**



## Start R&D work at consortium

- For CAR : Improvement of Resolution and Process window
  - For MOR : Development of MOR dedicated EUV-UL and SiHM.
- ⇒ Target to be the de fact standard materials for high-NA EUV.

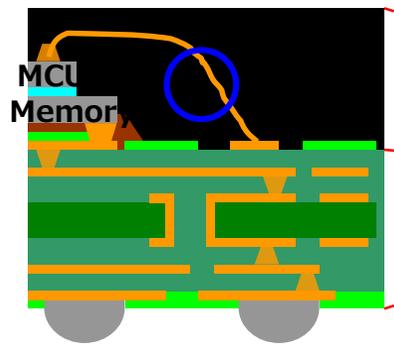
# C o n t e n t s

Introduction

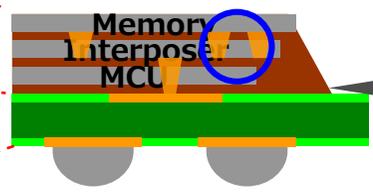
Lithography Materials  
(EUV Under layers)

**Packaging Materials**  
(Temporary bonding materials)

## X section of device

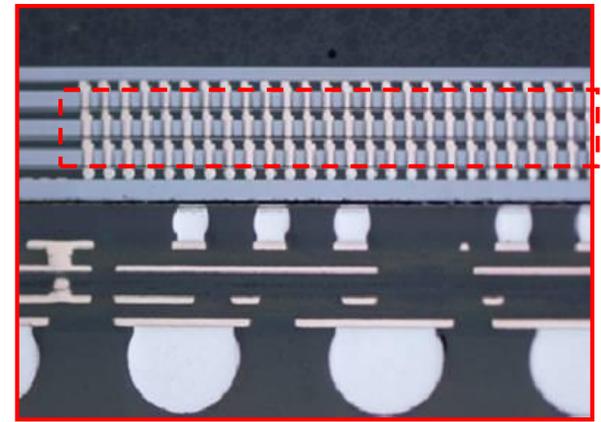


## Wire bonding to TSV



Small & High Speed

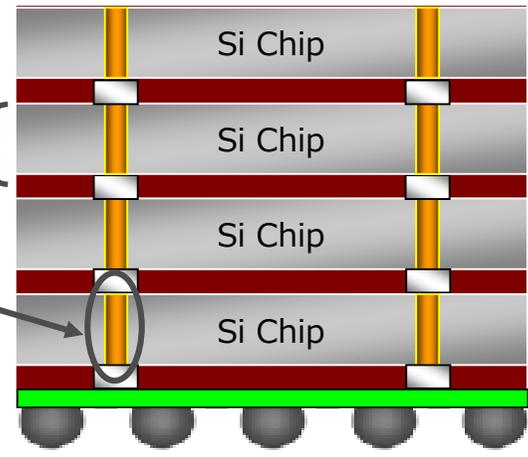
Thinned & stacked device connected by TSV



TSV (Through Silicon Via)

## Challenge for TSV

- Thin down (< 50um)
- High Temp. process



Special handling process and materials are necessary for wafer thin down process.



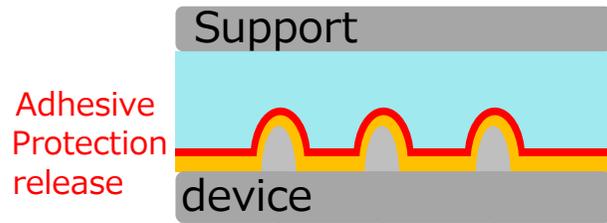
TWS (Thin Wafer Support System)

Laser type release layer will be required due to mechanical stress when wafer thickness will be thinner down.

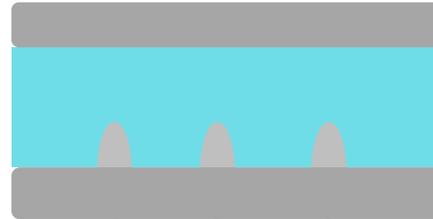
	Mechanical de-bond	Laser de-bond
Image	<p>Support</p> <p>Temporary bonding</p> <p>Thinned device wafer</p>	<p>Laser scan</p> <p>Glass wafer</p> <p>Temporary bonding</p> <p>Laser Release layer</p>
Merit	No limitation for Support wafer & CoO	No Mechanical stress
Challenge	Mechanical stress	Need Glass wafer for support

**NCC have been developing temporary bonding material for Mechanical de-bond and Laser de-bond process.**

## Mechanical de-bond



3 Layer  
Product



1 layer  
Product

Cost effective!

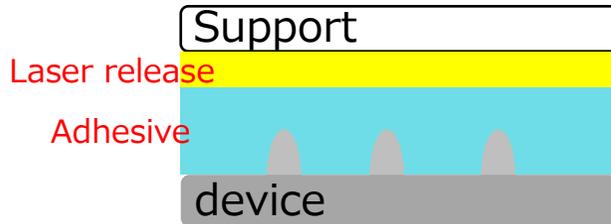


## Next Gen.

- TCB
- Hybrid Bonding

1 layer  
R&D

## Laser de-bond



2 layer  
Pilot stage



## Next Gen.

Cost effective!



1 layer  
R&D

NCC have Supported HVM in customer for ~HBM2 and developing next Gen. mechanical and laser de-bonding materials.

# Display Materials

# C o n t e n t s

LC Alignment Materials

New products

# C o n t e n t s

## LC Alignment Materials

New products

## To get high market share for growth fields

- Alignment layers for TV  
→rubbing IPS and VA
- Keep high market share of photo IPS  
→expanded application  
compatible products for carbon-neutral

# Strategy of Alignment Layers for Rubbing IPS

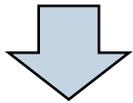
✓ New materials for wider viewing angle and better image sticking

## Rubbing process

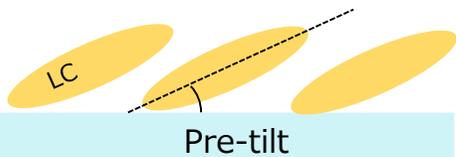
Rubbed alignment layer by cloth



Alignment layer



LC molecules align with pre-tilt.



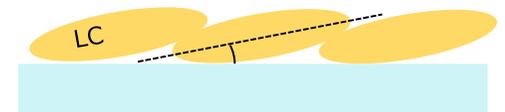
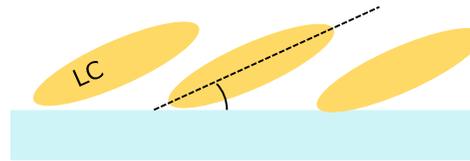
## Conventional

## New

LC alignment

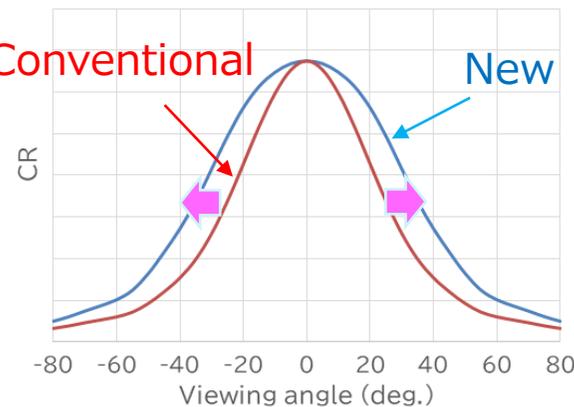


Pre-tilt



Viewing angle

Conventional New



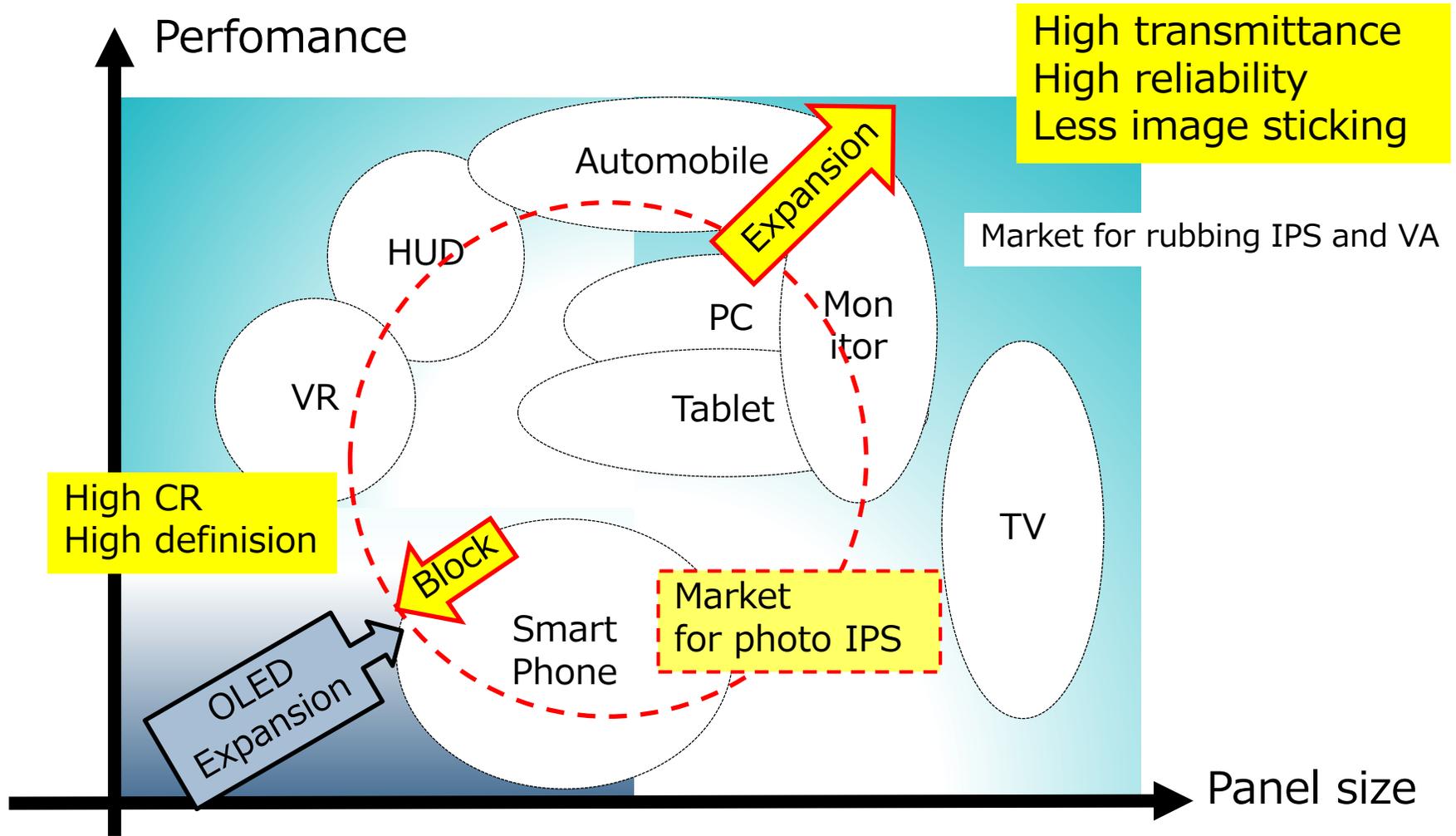
※Simulation

# Strategy of Alignment Layers for Photo VA

- ✓ New materials for higher transmittance photo VA-LCD  
→ new approach to narrow black line width

	Photo VA	Conventional	New
Method	Photo alignment		
LC alignment			
Voltage applied	<p>Black line generated at the boundary</p>		
Black line			
Transmittance		Low	High
CR		○	◎
Image sticking		○	○

# Strategy for Expanding Application of Photo IPS

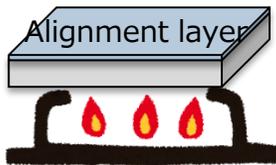


- ✓ Active movement toward carbon neutrality
- ✓ Huge power needed to manufacture display panels
  - Large amount of carbon dioxide emissions
- ✓ Increased demand for carbon footprint reduction
  - **Develop new materials that contribute to low power consumption**

- ✓ Aim to replace with environmentally friendly materials

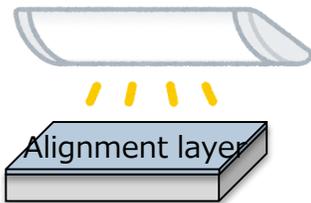
## ① Manufacturing process

### Lower baking temperature



Energy consumption reduction of ovens

### Lower UV dose



Energy consumption reduction of exposure devices

## ② LCD panel

### High transmittance/Low driving voltage

Energy consumption reduction of back light and driving circuit

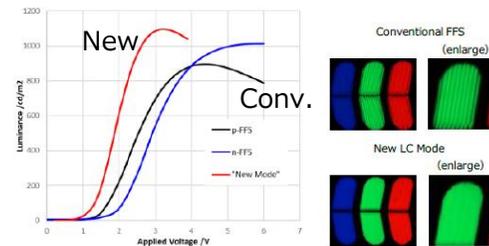


Fig. 2. Voltage-Transmittance characteristics and POM image at white state

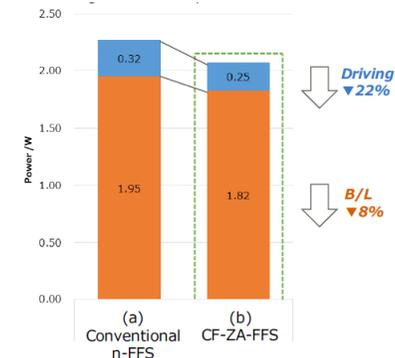


Fig. 6. Total power consumption of 14-inch FHD LCD modules at 60Hz white state for conventional n-FFS and CF-ZA-FFS (brightness: 500nits)

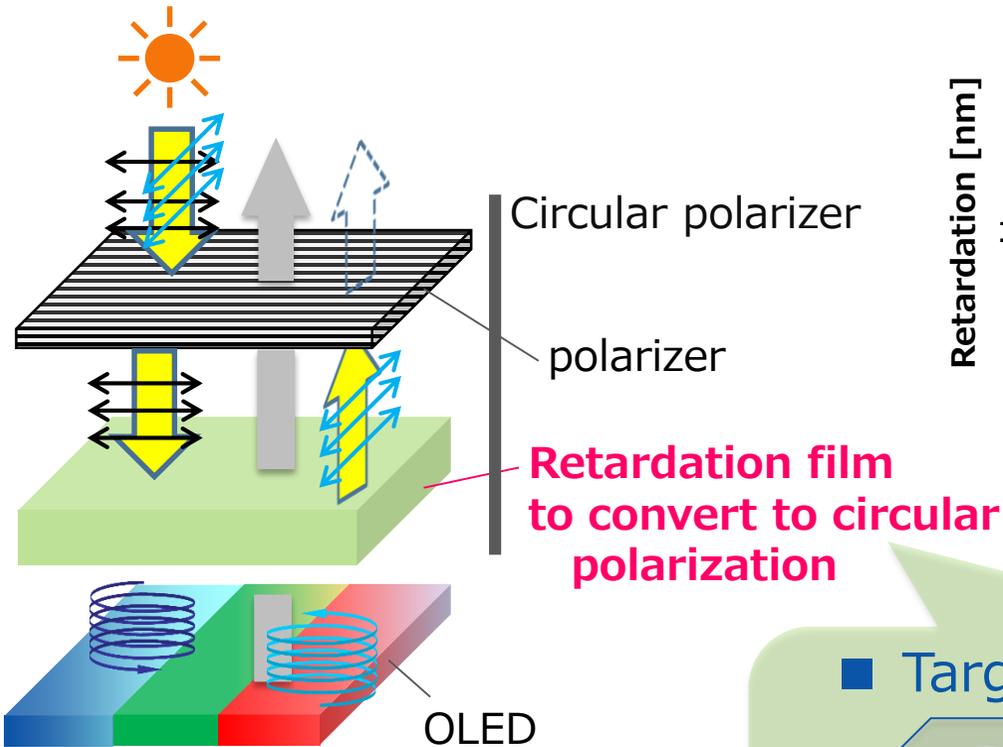
Source:H. Asagi, SID 2022 Digest, p337(2022)

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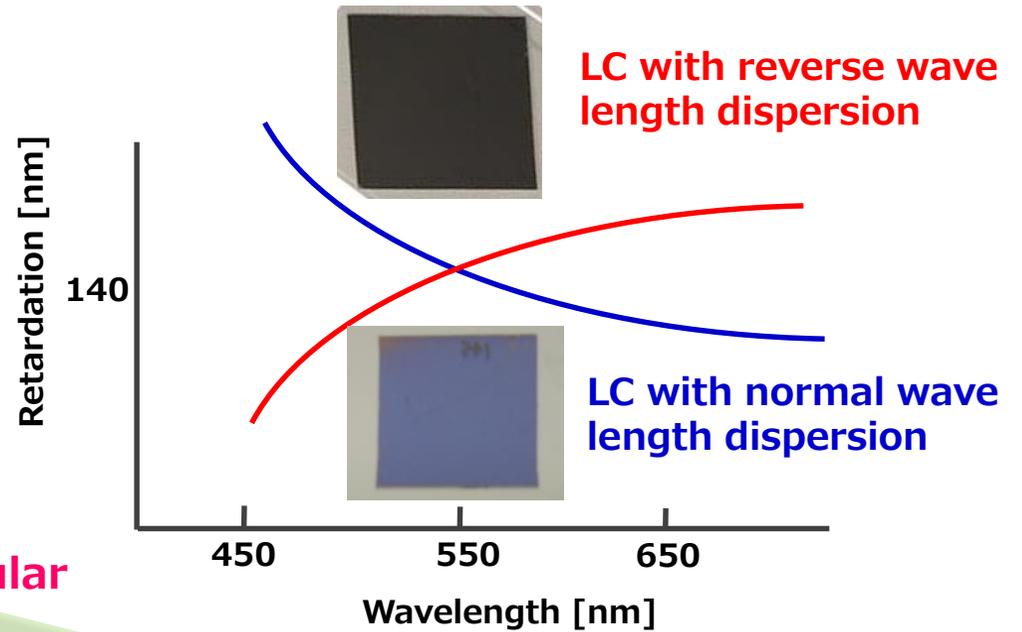
LC Alignment Materials

New products

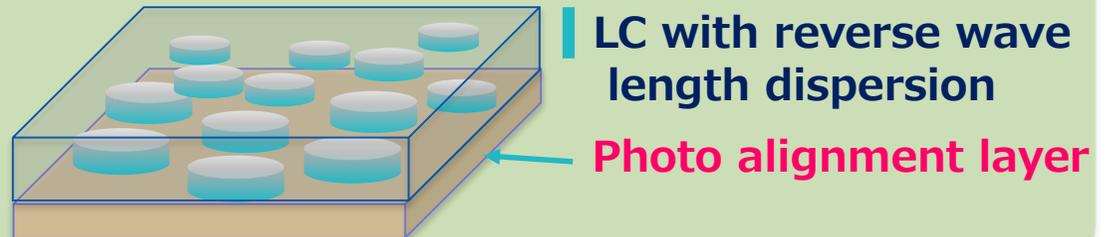
## ■ Circular polarizer



## ■ Wavelength dependence



## ■ Target ■



Point 1. Good alignmentability for LC with reverse wave length dispersion

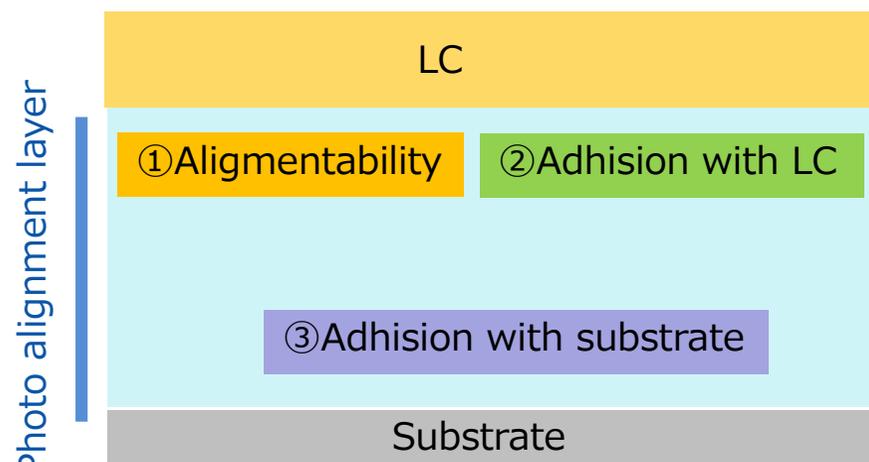


conventional : rod-like



new : not rod-like → difficult to get LC alignment uniformity

Point 2. **Good compatibility for process and substrate**



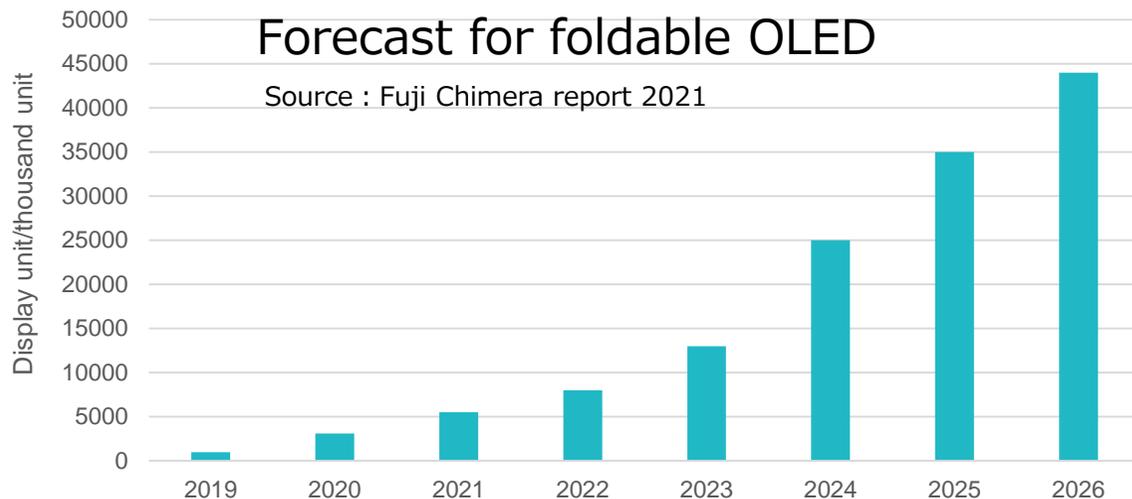
PET, TAC, acryl film, etc.

Possible to meet a variety of requests quickly

# Hard Coating Material (HC) for Foldable Displays

## Forecast for foldable OLED

Source : Fuji Chimera report 2021



**Our original surface control technology**

Foldable smartphone



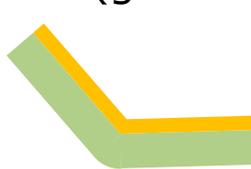
Source:Galaxy home page  
<https://www.galaxymobile.jp>

## Hard coating material

Protect Film

Film(PET, CPI...)

High stretchability  
 (good bending durability)



In folding



Out folding

Slippery  
 Antifouling  
 Scratch resistance



# Advanced Materials

# C o n t e n t s

## Display Materials for OLEDs

- ◆ Hole Injection Layer
- ◆ Bank Material
- ◆ De-Bonding Layer
- ◆ Light Extraction Enhancement Material

## Display Materials for Micro-LEDs

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## Display Materials for OLEDs

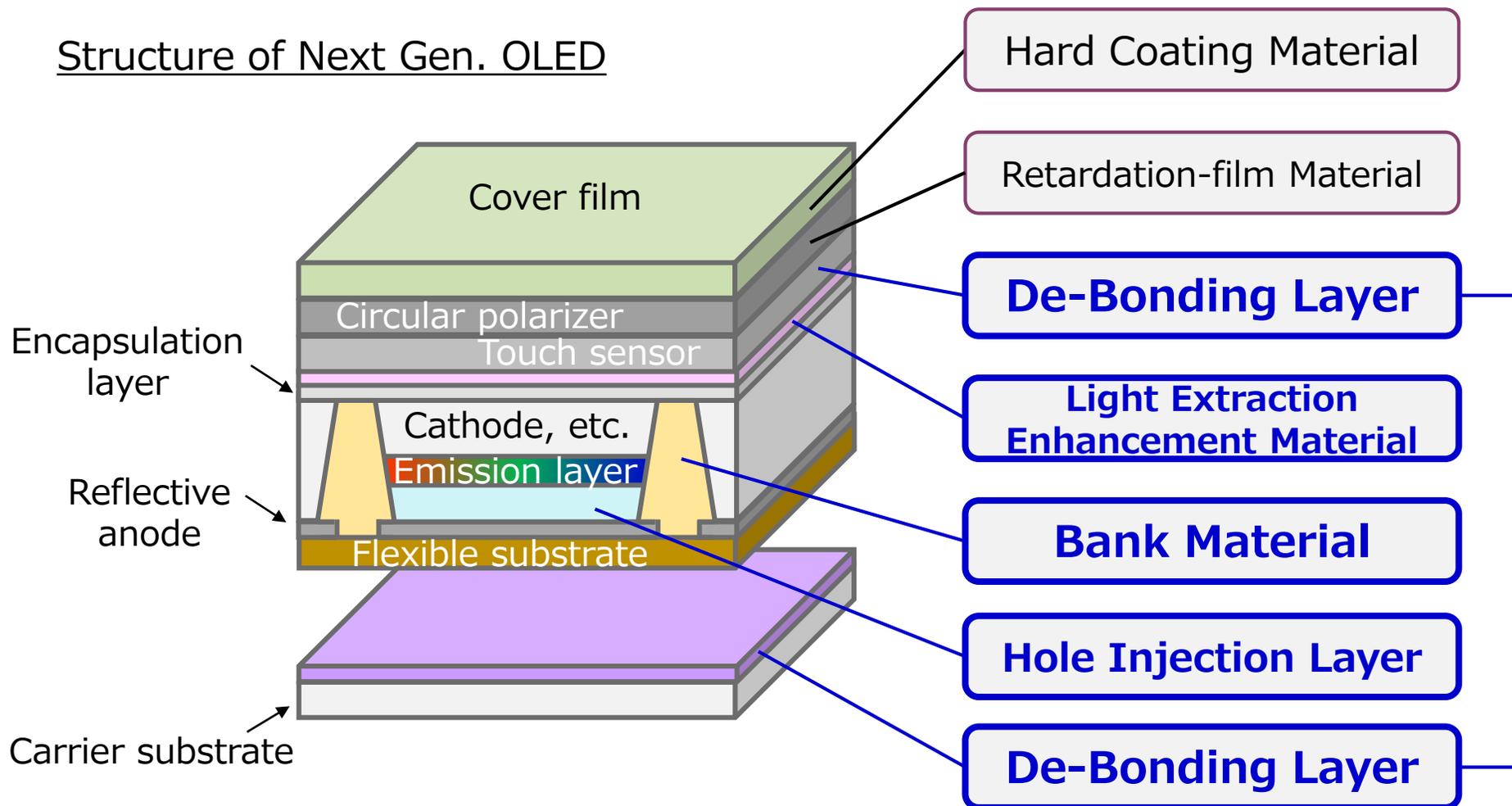
- ◆ Hole Injection Layer
- ◆ Bank Material
- ◆ De-Bonding Layer
- ◆ Light Extraction Enhancement Material

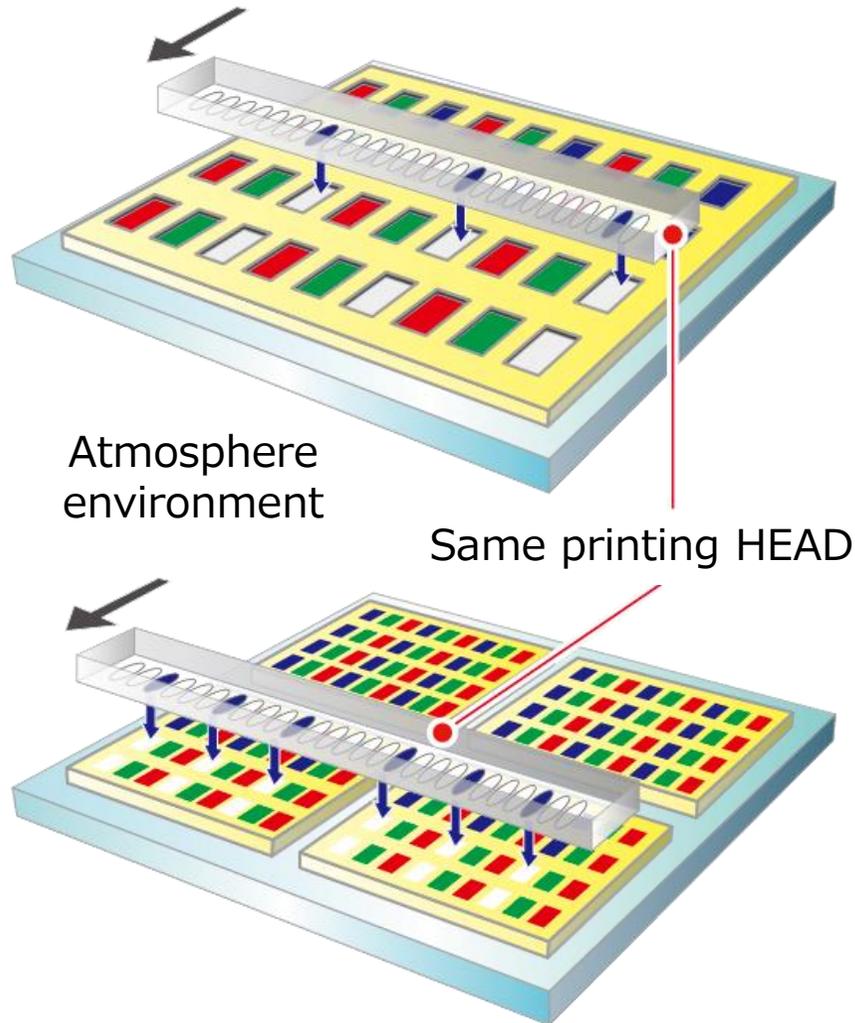
## Display materials for Micro-LEDs

## Materials for Eco-friendly processes & devices

- Next Gen. processes: **Hole Injection Layer, Bank Material, De-Bonding Layer**
- Next Gen. devices : **Light Extraction Enhancement Material**

## Structure of Next Gen. OLED





(1) Printing process: use only required material and quantity

(2) Atmospheric environment: apply eco-friendly equipment

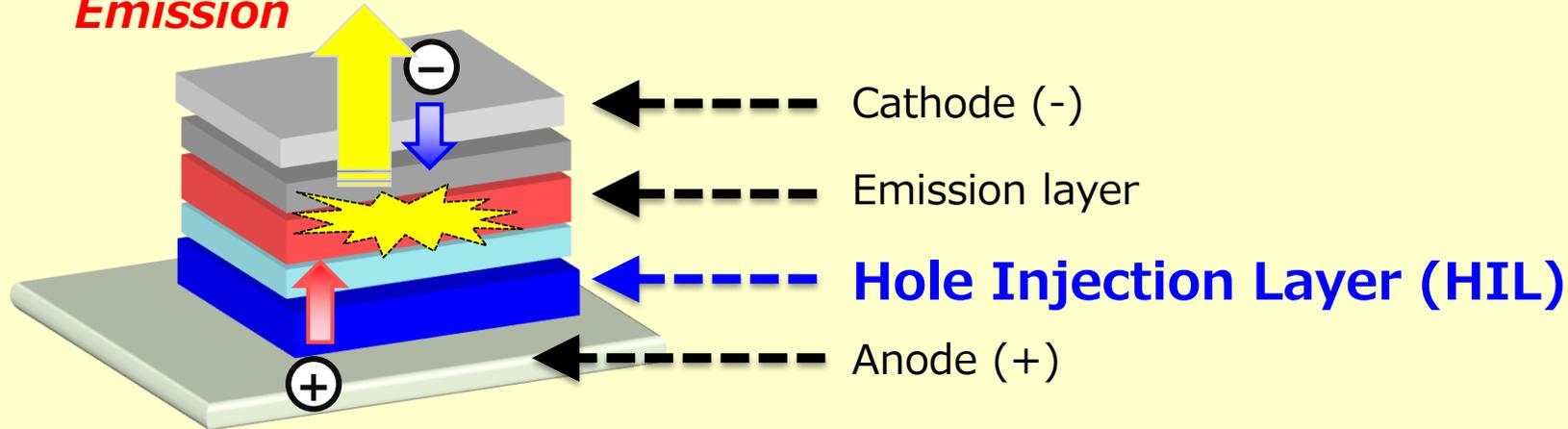
(3) Suitable for large-size substrates: metal mask less

**→ Hole Injection Layer & Bank Material**

Source: JOLED, 2018

(<https://www.j-oled.com/eng/technology/>)

**Emission**



## Purpose

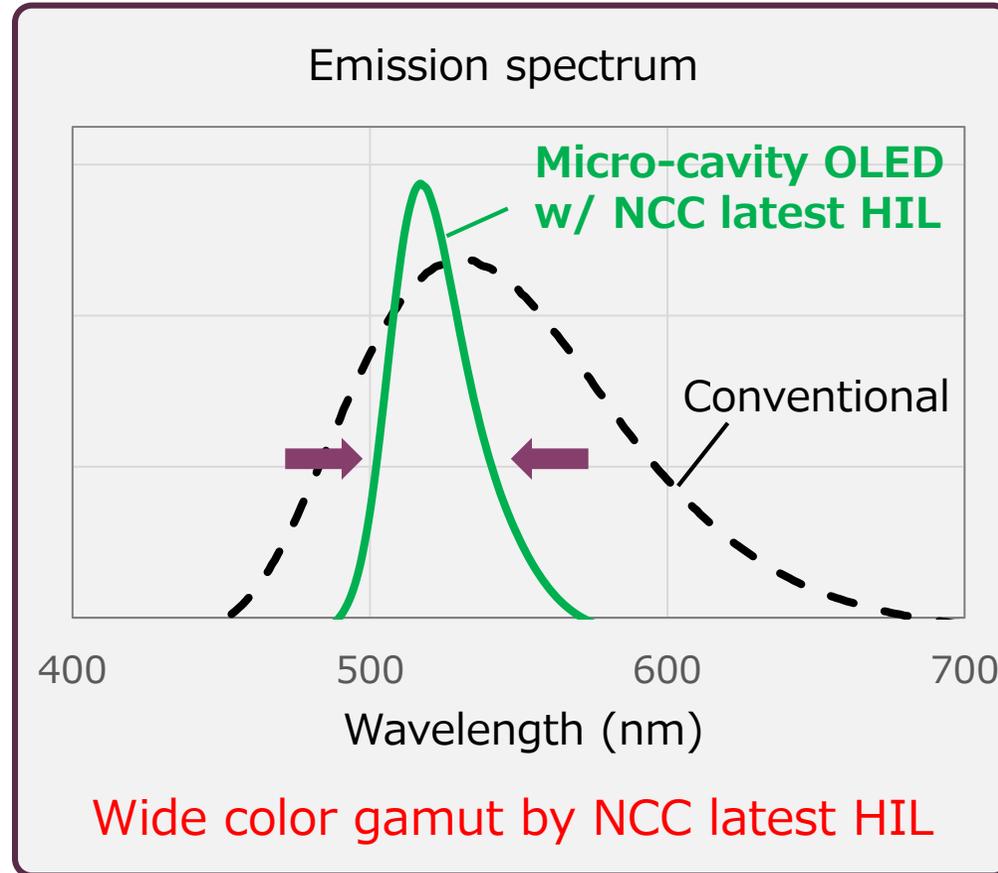
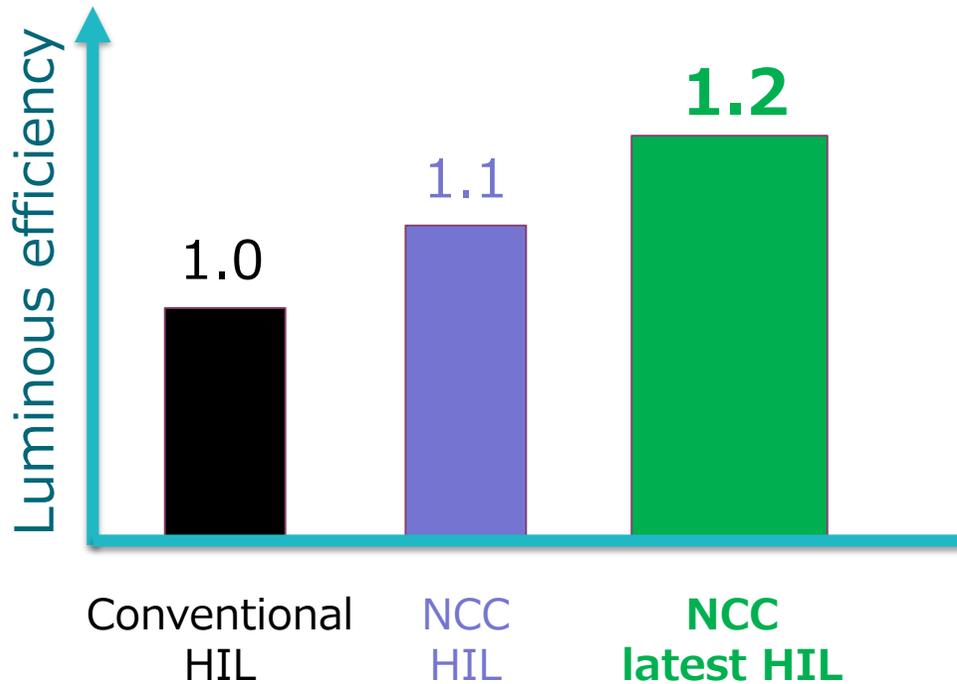
- Effectively inject hole to emission layer
- Optimize both hole injection efficiency and optical properties

## Features

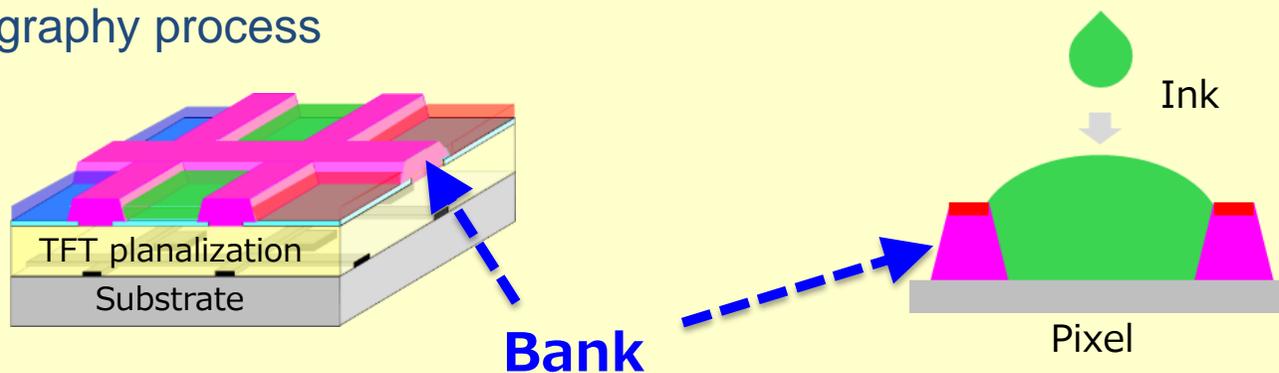
- Low power consumption
- Long life time
- Suitable to fit micro-cavity structure

## Our approach

Electrical property/ High definition inkjet printing + **World's largest control range of refractive index**



Fabricate bank around pixel by photo lithography process



## Purpose

- Ensure uniformity of inks in pixel area
- Hydrophobic bank surface to fit any device structures

## Features

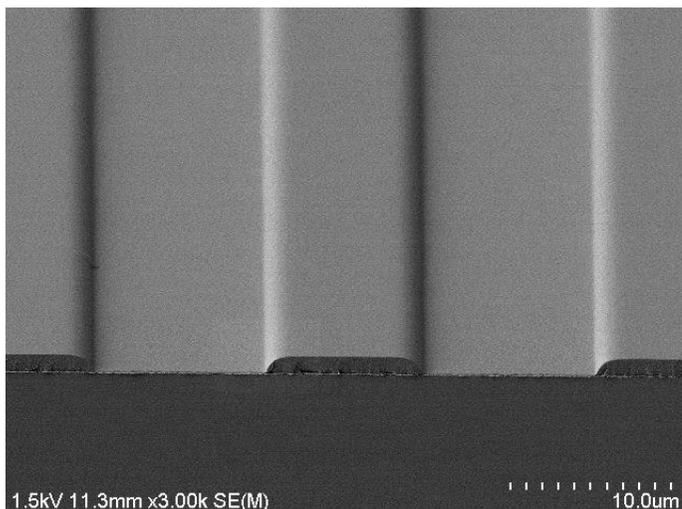
- Stable luminous property with bringing out the best in each layer
- Fine pitch patterning without color mixing
- High production yield

## Our approach

High resolution, high sensitivity, no residue (excellent wettability of inks),  
no out-gas

→ Fit to any device structures and pixel pitches

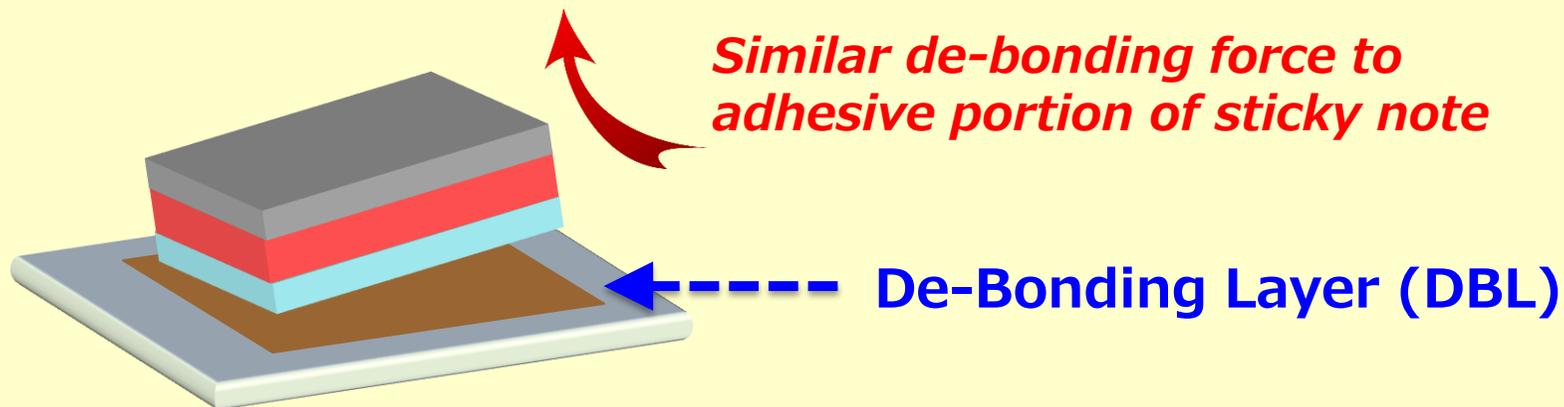
→ **Maximum luminous efficiency combined with NCC HIL**



SEM picture



Inkjet printing of NCC HIL at areas surrounded  
by banks



## Purpose

- Coat de-bonding layer on carrier glasses for flexible displays
- Control de-bonding force to fit any device structures

## Features

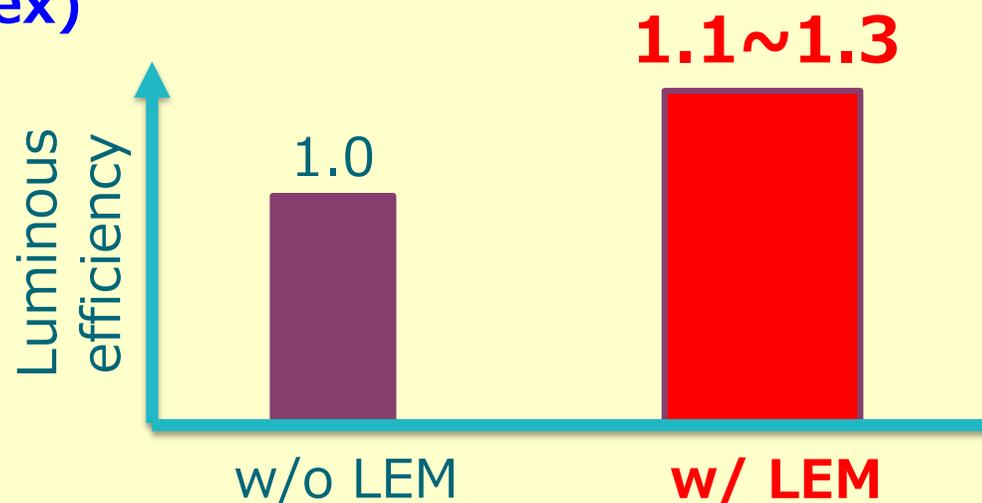
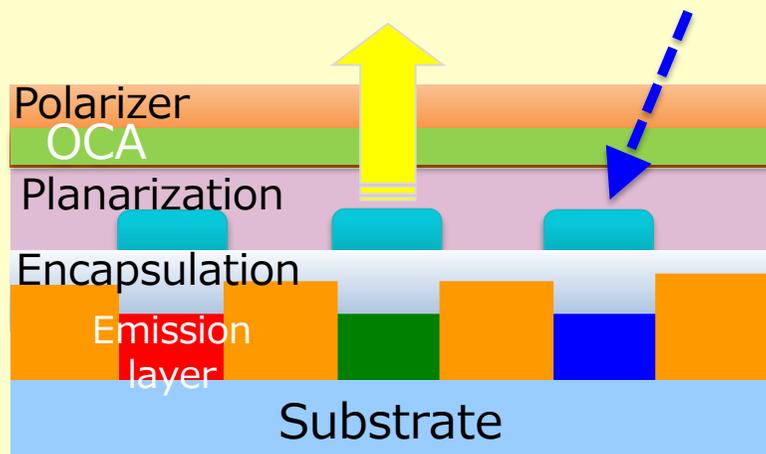
- Stable keeping & de-bonding forces
- Eco-friendly process with low running cost
- Re-use carrier substrates easily
- Can apply printing machines in current LCD Fabs.

## Our approach

- Excellent de-bonding properties to any film substrates
  - Excellent heat resistance to fit any manufacturing processes
- Differentiation to conventional laser lift-off process by the features of eco-friendly & low running cost

Items	Our DBL
Film substrates	Epoxy, Polyimide, etc.
Process temperature	180~450°C
Printing process	Spin coating, Slit coating, Flexographic printing, etc.

## LEM (pattern-able w/ high refractive index)



### Purpose

- Effectively out-coupling of emission light

### Features

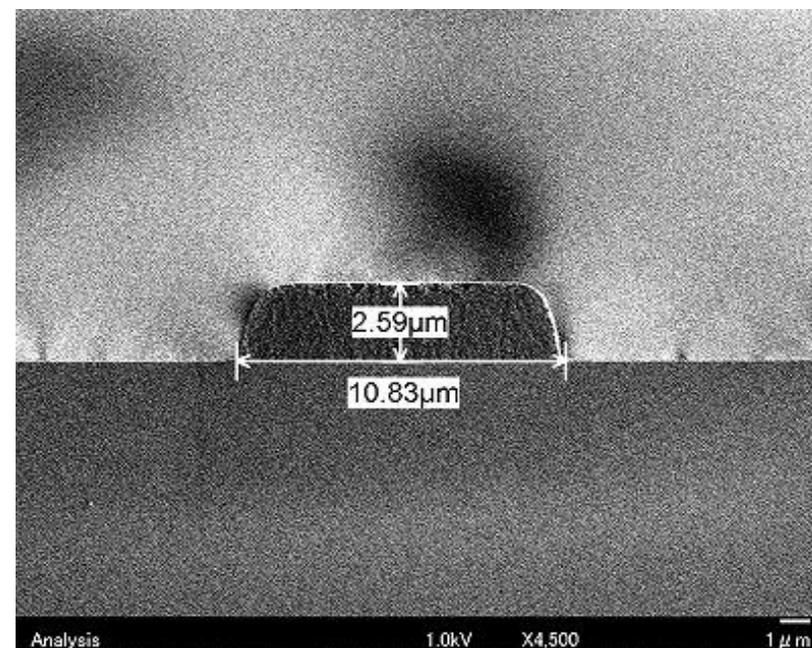
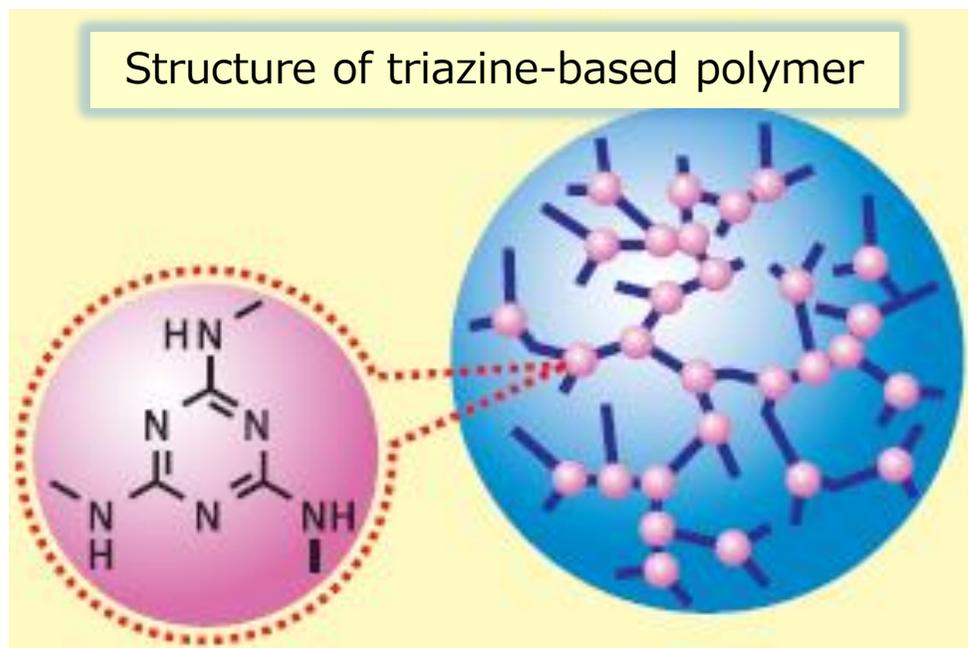
- 10~30% higher luminous efficiency → Low power consumption
- Long life time

## Our approach

Our original triazine-based polymer w/ high refractive index

→ Photo lithography without residue (both rectangular & lens)

→ Adjustable refractive index within the range from 1.5 to 1.9



SEM picture

# C o n t e n t s

## Display Materials for OLEDs

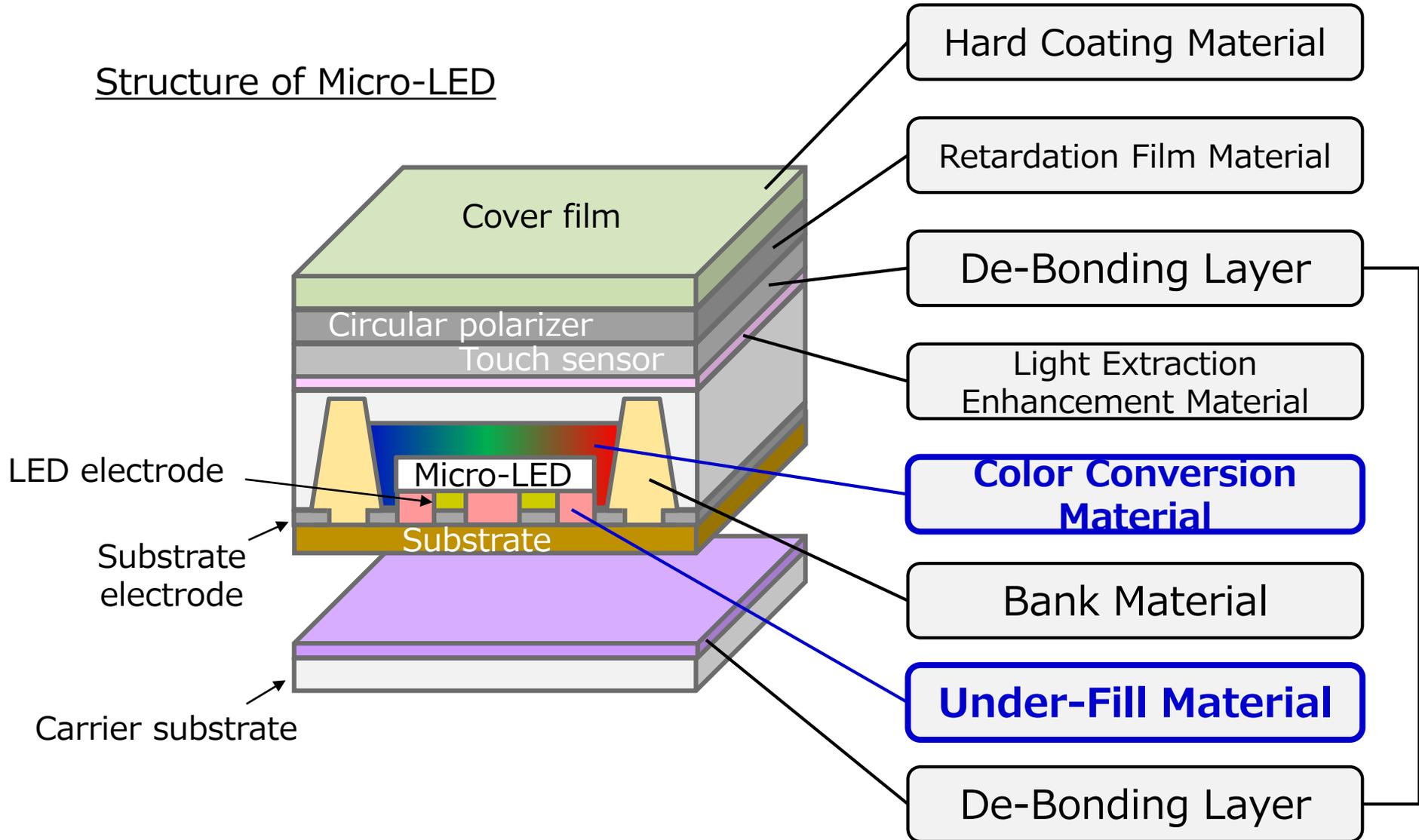
- ◆ Hole Injection Layer
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- ◆ De-Bonding Layer
- ◆ Light Extraction Enhancement Material

## Display Materials for Micro-LEDs

## Materials for eco-friendly Micro-LEDs

- Wide color gamut: **Color Conversion Material**
- High reliability: **Under-Fill Material**

## Structure of Micro-LED



# Inorganic Materials

# C o n t e n t s

Inorganic Colloid Materials

Development of Environmentally  
Friendly Materials

# C o n t e n t s

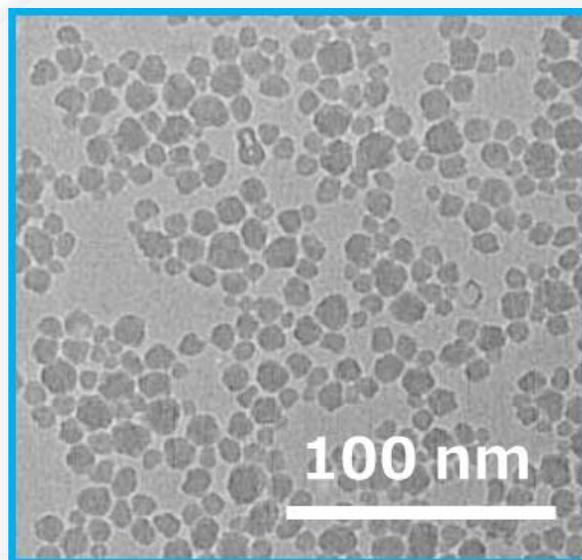
## Inorganic Colloid Materials

Development of Environmentally  
Friendly Materials

# What is an Inorganic Colloidal Material?

A material in which nano-sized fine particles are dispersed in a solvent (water, organic solvent, monomer).

## Typical product “ SNOWTEX-30 ”



Nanoparticles of Silica sol

Particle size : 12 nm

Solid content : 30 wt%

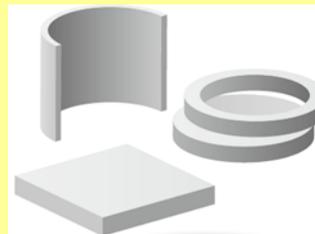
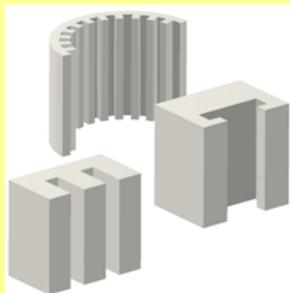
$\Rightarrow 15 \times 10^{16}$  count/g



Casting  
(mold)



Ceramics



**Binder**  
Heat resistance



Catalyst

SNOWTEX®  
ORGANOSILLCASOL  
ALUMINASOL  
NanoUse®  
SUNCOLLOID®

**Coating**

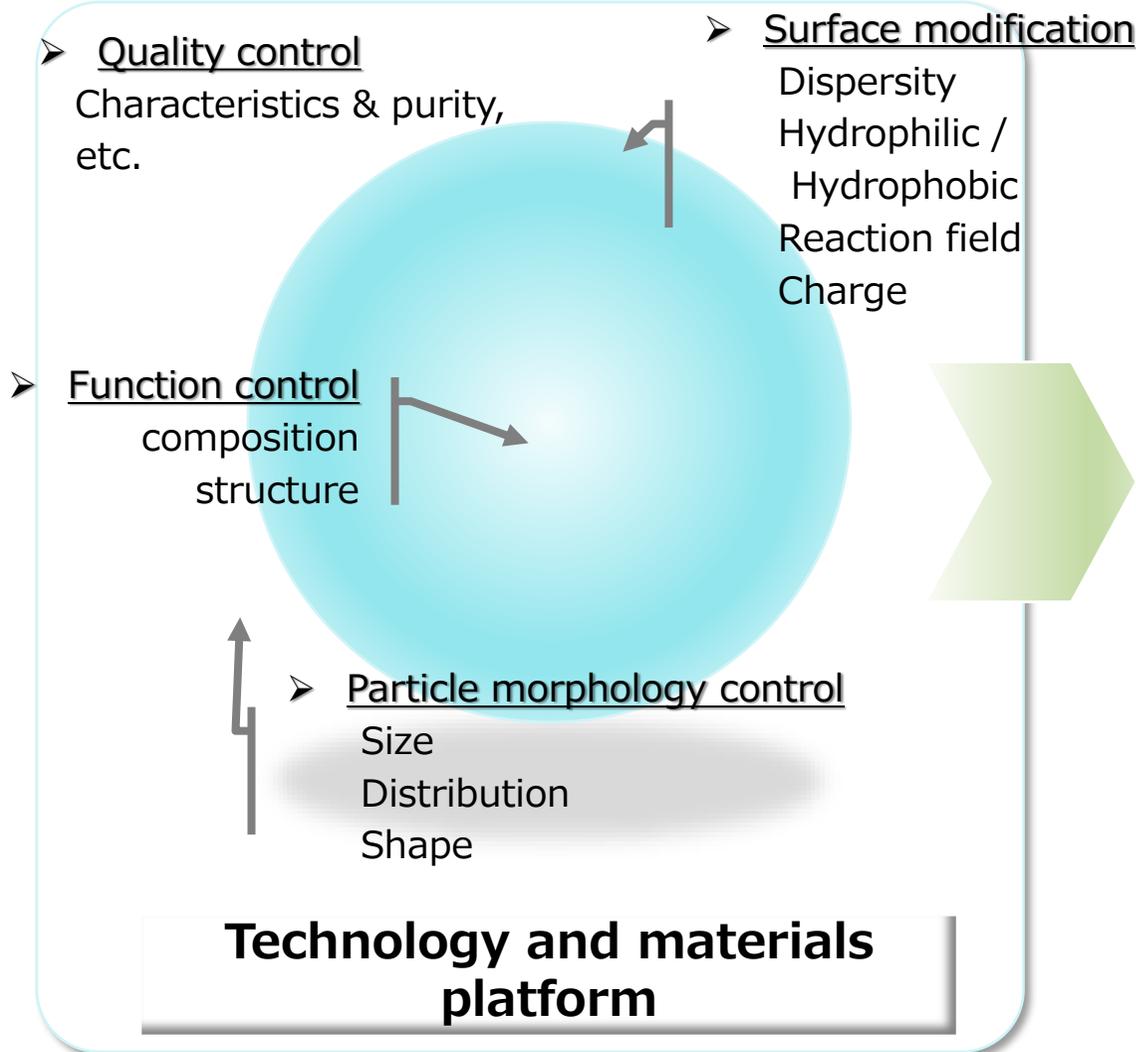


**Polishing**

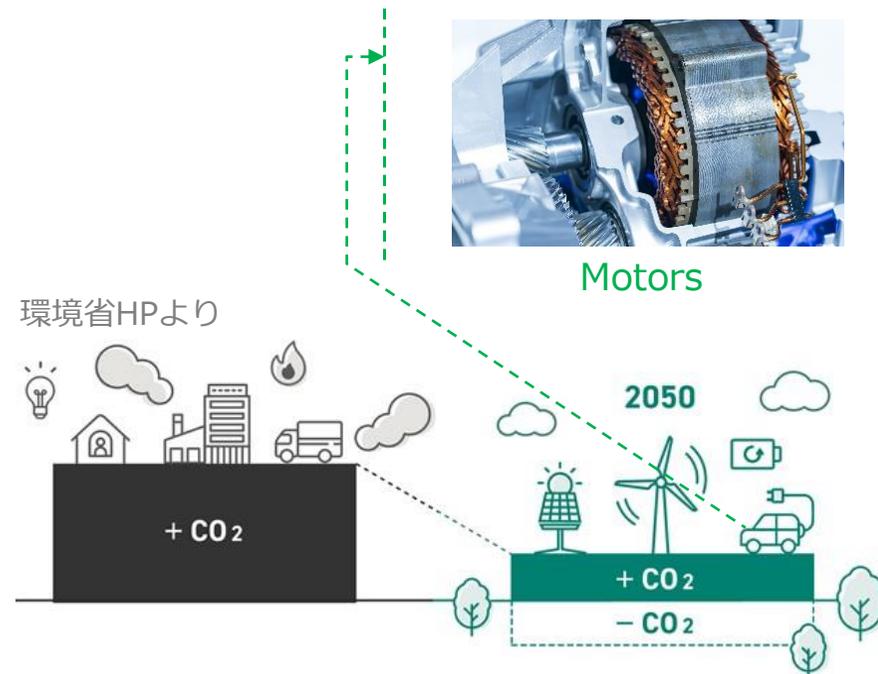


## Research materials (value) that will continue into the future

... Respond to market & needs



## Carbon neutrality



**Apply to environmentally friendly materials**

# C o n t e n t s

Inorganic Colloid Materials

Development of Environmentally  
Friendly Materials

## ■ Movement to achieve carbon neutrality



CO<sub>2</sub> reduction :

- ① Related to Electric vehicle (EV)

CO<sub>2</sub> storage / utilization :

- ② Related to CCS / CCUS※

※Carbon dioxide Capture, Utilization and Storage



EV/TESLA



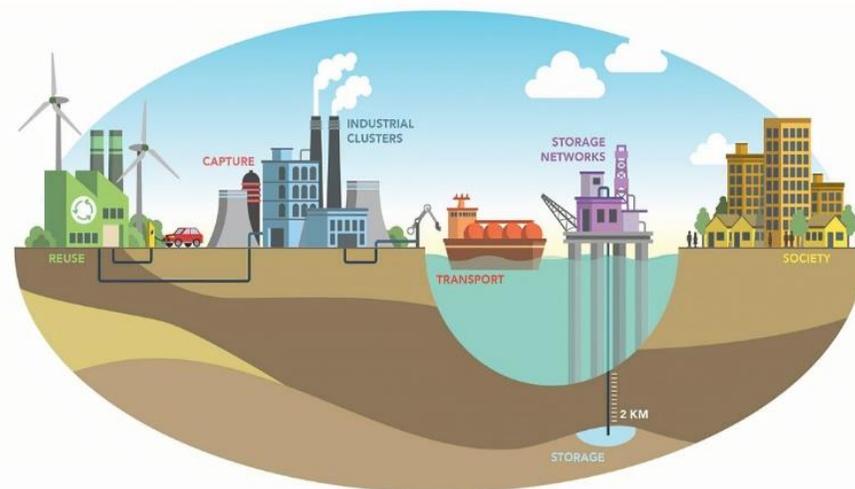
EV/BYD



Motors

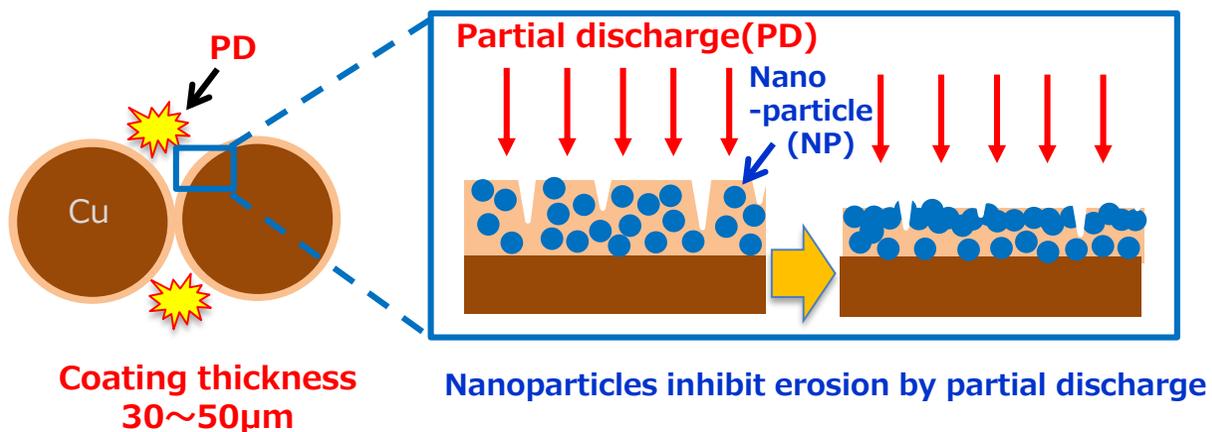


Enameled wire

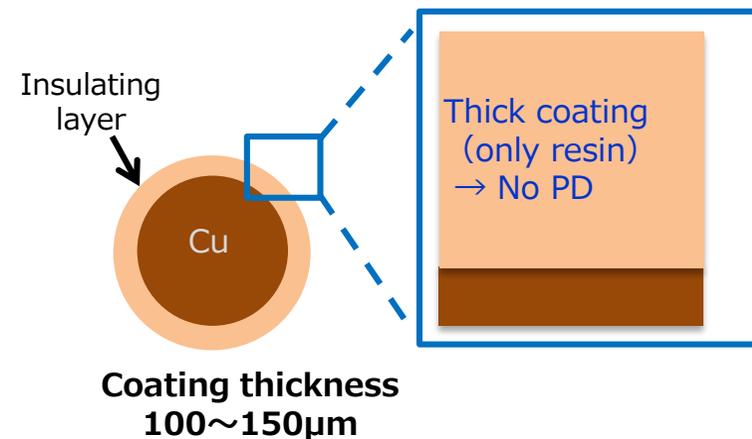


## ✓ Higher output/more compact EV motors

### Surge-resistant enamelled wire (w/NP)



### High PDIV enamelled wire



Advantages of Surge-resistant type :

- High allowable voltage
  - High copper wire occupancy
- ⇒ Higher output and smaller motor

Enamelled wire	Surge-rst	High-PDIV
Composition of insulating layer	PI+NP	low-d PI
Higher output	++	+
Smaller size	++	+
Insulation lifetime	+	++

## ✓ Improvement of nanoparticles

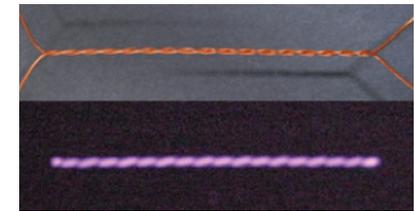
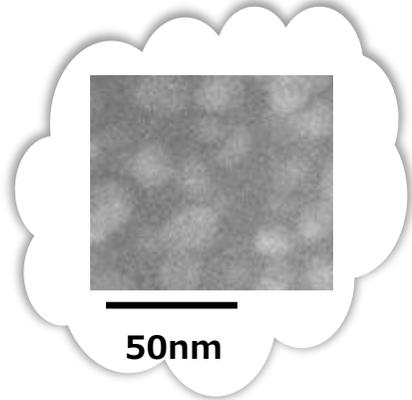
Nanoparticle



Insulating varnish

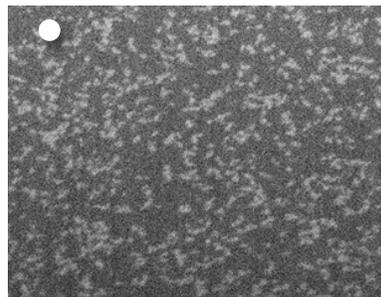


Enameled wire



## ✓ Nanocomposite & Insulation evaluation

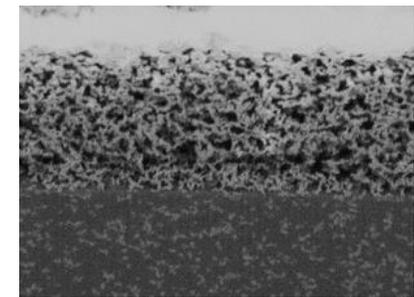
PI/silica nanocomposite



1µm



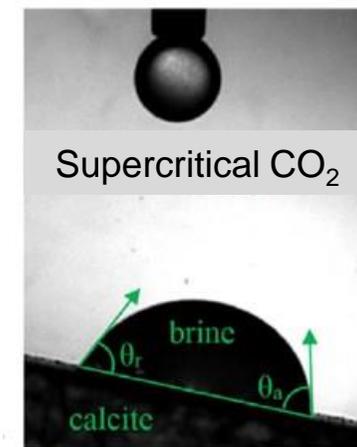
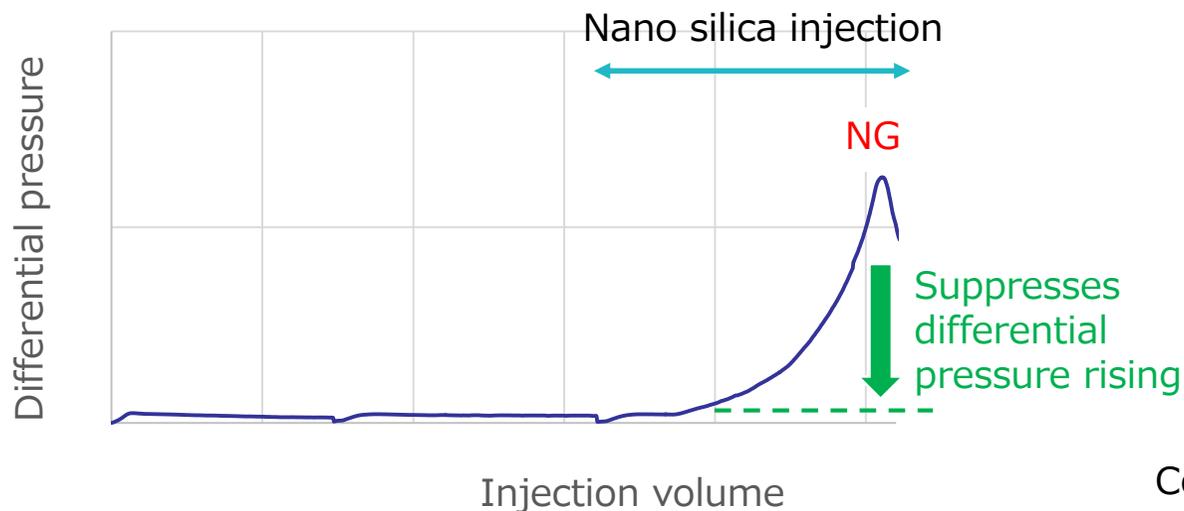
Enameled wire evaluation



1µm

## ✓ Fusion of nanoparticles and surface chemistry

Development of nanoparticle fluid		Expected function
Dispersibility (salt tolerance)	Stable under formation condition	No clogging in the injection process (No pressure rising)
Interfacial tension	Controlled to the same level as salt water	Leakage suppression of CO <sub>2</sub>
Contact angle	Wettability modification of rock surface	Increasing CO <sub>2</sub> storage



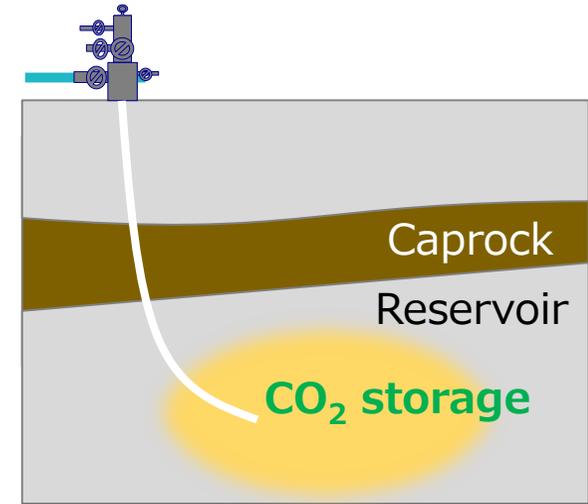
Contact angle measurement

## ✓ Collaboration with development partners

### CCS(Carbon dioxide Capture and Storage) :

Collaborate with the Australian national research institute and a university

Started development of new materials that can significantly increase CO<sub>2</sub> storage

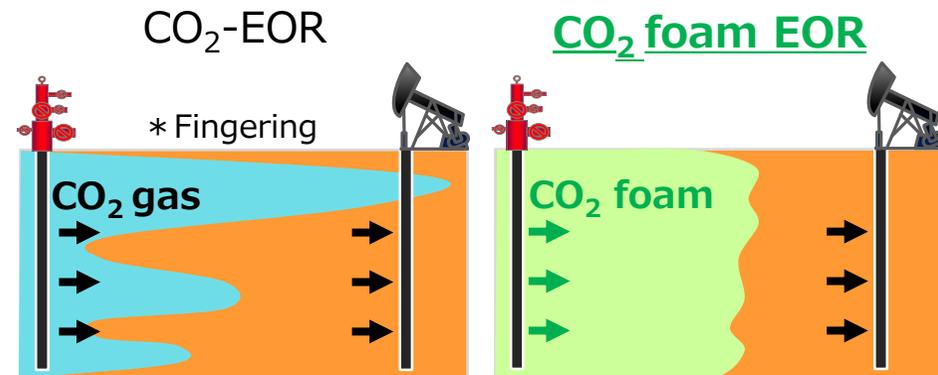


### CCUS(Carbon dioxide Capture, Utilization and Storage) :

To solve existing CO<sub>2</sub> EOR issues \*

Developed a new material to stabilize CO<sub>2</sub> foam

Planning a field test with a domestic oil company and a university this year



*Fin.*

Thank you for your attention.

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